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R8C/26 Group, R8C/27 Group SINGLE-CHIP 16-BIT CMOS MCU

REJ03B0168-0210 Rev.2.10 Sep 26, 2008

1. **Overview**

These MCUs are fabricated using a high-performance silicon gate CMOS process, embedding the R8C CPU core, and are packaged in a 32-pin molded-plastic LQFP. It implements sophisticated instructions for a high level of instruction efficiency. With 1 Mbyte of address space, they are capable of executing instructions at high speed.

Furthermore, the R8C/27 Group has on-chip data flash (1 KB \times 2 blocks).

The difference between the R8C/26 Group and R8C/27 Group is only the presence or absence of data flash. Their peripheral functions are the same.

1.1 **Applications**

Electronic household appliances, office equipment, audio equipment, consumer products, automotive, etc.



1.2 Performance Overview

Table 1.1 outlines the Functions and Specifications for R8C/26 Group and Table 1.2 outlines the Functions and Specifications for R8C/27 Group.

Table 1.1 Functions and Specifications for R8C/26 Group

ODLI	Item	Specification
CPU	Number of	89 instructions
	fundamental	
	instructions Minimum instruction	50 ns (f(XIN) = 20 MHz, VCC = 3.0 to 5.5 V) (other than K version)
	execution time	62.5 ns (f(XIN) = 20 MHz, VCC = 3.0 to 5.5 V) (MINER THAIL K VERSION)
	execution time	100 ns (f(XIN) = 10 MHz, VCC = 2.7 to 5.5 V)
		200 ns (f(XIN) = 5 MHz, VCC = 2.2 to 5.5 V) (N, D version)
	Operating mode	Single-chip
	Address space	1 Mbyte
5	Memory capacity	Refer to Table 1.3 Product Information for R8C/26 Group
Peripheral	Ports	I/O ports: 25 pins, Input port: 3 pins
Functions	LED drive ports	I/O ports: 8 pins (N, D version)
	Timers	Timer RA: 8 bits x 1 channel
		Timer RB: 8 bits x 1 channel
		(Each timer equipped with 8-bit prescaler)
		Timer RC: 16 bits x 1 channel
		(Input capture and output compare circuits)
		Timer RE: With real-time clock and compare match function
		(For J, K version, compare match function only.)
	Serial interfaces	2 channels (UART0, UART1)
		Clock synchronous serial I/O, UART
	Clock synchronous	1 channel
	serial interface	I ² C bus Interface ⁽¹⁾
		Clock synchronous serial I/O with chip select
	LIN module	Hardware LIN: 1 channel (timer RA, UART0)
	A/D converter	10-bit A/D converter: 1 circuit, 12 channels
	Watchdog timer	15 bits x 1 channel (with prescaler)
		Start-on-reset selectable
	Interrupts	Internal: 15 sources, External: 4 sources,
		Software: 4 sources, Priority levels: 7 levels
	Clock generation	3 circuits
	circuits	XIN clock generation circuit (with on-chip feedback resistor)
		On-chip oscillator (high speed, low speed)
		High-speed on-chip oscillator has a frequency adjustment function
		XCIN clock generation circuit (32 kHz) (N, D version)
		Real-time clock (timer RE) (N, D version)
	Oscillation-stopped	XIN clock oscillation stop detection function
	detector	7.114 Glock Goomation Gtop actodion function
	Voltage detection	On-chip
	circuit	Off offip
	Power-on reset circuit	On-chip
Electrical	Supply voltage	VCC = 3.0 to 5.5 V (f(XIN) = 20 MHz) (other than K version)
Characteristics	Supply voltage	VCC = 3.0 to 5.5 V (f(XIN) = 20 MHz) (other trial it version)
Citaracteristics		VCC = 2.7 to 5.5 V (f(XIN) = 10 MHz)
		VCC = 2.2 to 5.5 V (f(XIN) = 10 MHz) (N, D version)
	Current consumption	Typ. 10 mA (VCC = 5.0 V, f(XIN) = 20 MHz)
	(N, D version)	Typ. 6 mA (VCC = 3.0 V , f(XIN) = 20 MHz)
	(IV, D Version)	Typ. 2.0 μ A (VCC = 3.0 V, wait mode (f(XCIN) = 32 kHz)
		Typ. 0.7 μ A (VCC = 3.0 V, wait mode (I(XCIN) = 32 KHz)
Flash Memory	Programming and	VCC = 2.7 to 5.5 V
i idəli ivi c ililliy	erasure voltage	V 00 - 2.7 (0 0.0 V
	Programming and	100 times
		100 tillies
On a ratio = A!-	erasure endurance	20 to 95°C (N version)
Operating Ambie	int remperature	-20 to 85°C (N version)
		-40 to 85°C (D, J version) ⁽²⁾ , -40 to 125°C (K version) ⁽²⁾
Package		32-pin molded-plastic LQFP

- 1. I²C bus is a trademark of Koninklijke Philips Electronics N. V.
- 2. Specify the D, K version if D, K version functions are to be used.



Table 1.2 Functions and Specifications for R8C/27 Group

	Item	Specification
CPU	Number of fundamental	89 instructions
	instructions	
	Minimum instruction	50 ns (f(XIN) = 20 MHz, VCC = 3.0 to 5.5 V) (other than K version)
	execution time	62.5 ns (f(XIN) = 16 MHz, VCC = 3.0 to 5.5 V) (K version)
		100 ns (f(XIN) = 10 MHz, VCC = 2.7 to 5.5 V)
		200 ns (f(XIN) = 5 MHz, VCC = 2.2 to 5.5 V) (N, D version)
	Operating mode	Single-chip
	Address space	1 Mbyte
	Memory capacity	Refer to Table 1.4 Product Information of R8C/27 Group
Peripheral	Ports	I/O ports: 25 pins, Input port: 3 pins
Functions	LED drive ports	I/O ports: 8 pins (N, D version)
	Timers	Timer RA: 8 bits x 1 channel
		Timer RB: 8 bits x 1 channel
		(Each timer equipped with 8-bit prescaler)
		Timer RC: 16 bits x 1 channel
		(Input capture and output compare circuits)
		Timer RE: With real-time clock and compare match function
		(For J, K version, compare match function only.)
	Serial interfaces	2 channels (UART0, UART1)
		Clock synchronous serial I/O, UART
	Clock synchronous	1 channel
	serial interface	I ² C bus Interface ⁽¹⁾
		Clock synchronous serial I/O with chip select
	LIN module	Hardware LIN: 1 channel (timer RA, UART0)
	A/D converter	10-bit A/D converter: 1 circuit, 12 channels
	Watchdog timer	15 bits x 1 channel (with prescaler)
		Start-on-reset selectable
	Interrupts	Internal: 15 sources, External: 4 sources,
		Software: 4 sources, Priority levels: 7 levels
	Clock generation	3 circuits
	circuits	XIN clock generation circuit (with on-chip feedback resistor)
		On-chip oscillator (high speed, low speed) Ulink and all the procedure of the speed from t
		High-speed on-chip oscillator has a frequency adjustment function
		 XCIN clock generation circuit (32 kHz) (N, D version) Real-time clock (timer RE) (N, D version)
	Oscillation stanced	XIN clock oscillation stop detection function
	Oscillation-stopped detector	And clock oscillation stop detection function
	Voltage detection circuit	On chin
	Power-on reset circuit	On-chip
Electrical	Supply voltage	VCC = 3.0 to 5.5 V (f(XIN) = 20 MHz) (other than K version)
Characteristics	Supply voltage	VCC = 3.0 to 5.5 V (f(XIN) = 26 MHz) (Warsion)
Characteristics		VCC = 2.7 to 5.5 V (f(XIN) = 10 MHz)
		VCC = 2.2 to 5.5 V (f(XIN) = 5 MHz) (N, D version)
	Current consumption	Typ. 10 mA (VCC = 5.0 V, f(XIN) = 20 MHz)
	(N, D version)	Typ. 6 mA (VCC = 3.0 V, f(XIN) = 10 MHz)
	(14, 2 voloion)	Typ. 2.0 μ A (VCC = 3.0 V, wait mode (f(XCIN) = 32 kHz)
		Typ. 0.7 μ A (VCC = 3.0 V, stop mode)
Flash Memory	Programming and	VCC = 2.7 to 5.5 V
	erasure voltage	
	Programming and	10,000 times (data flash)
	erasure endurance	1,000 times (gram ROM)
Operating Ambie		-20 to 85°C (N version)
		-40 to 85°C (D, J version) ⁽²⁾ , -40 to 125°C (K version) ⁽²⁾
Package		32-pin molded-plastic LQFP
i dokay o		02 piii molded-piastic Eq. i

- 1. I^2C bus is a trademark of Koninklijke Philips Electronics N. V.
- 2. Specify the D, K version if D, K version functions are to be used.



1.3 Block Diagram

Figure 1.1 shows a Block Diagram.

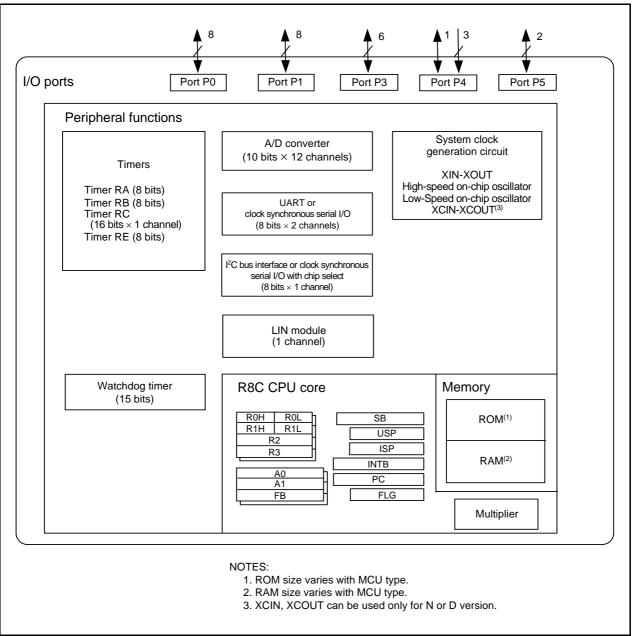


Figure 1.1 Block Diagram

1.4 **Product Information**

Table 1.3 lists the Product Information for R8C/26 Group and Table 1.4 lists the Product Information for R8C/27 Group.

Table 1.3 **Product Information for R8C/26 Group**

Current of Sep. 2008

Dowt No.	ROM	RAM	Dookson Time	De	
Part No.	Capacity	Capacity	Package Type	Re	emarks
R5F21262SNFP	8 Kbytes	512 bytes	PLQP0032GB-A	N version	
R5F21264SNFP	16 Kbytes	1 Kbyte	PLQP0032GB-A		
R5F21265SNFP	24 Kbytes	1.5 Kbytes	PLQP0032GB-A]	
R5F21266SNFP	32 Kbytes	1.5 Kbytes	PLQP0032GB-A]	
R5F21262SDFP	8 Kbytes	512 bytes	PLQP0032GB-A	D version	
R5F21264SDFP	16 Kbytes	1 Kbyte	PLQP0032GB-A]	
R5F21265SDFP	24 Kbytes	1.5 Kbytes	PLQP0032GB-A		
R5F21266SDFP	32 Kbytes	1.5 Kbytes	PLQP0032GB-A]	
R5F21264JFP	16 Kbytes	1 Kbyte	PLQP0032GB-A	J version	
R5F21266JFP	32 Kbytes	1.5 Kbytes	PLQP0032GB-A		
R5F21264KFP	16 Kbytes	1 Kbyte	PLQP0032GB-A	K version	
R5F21266KFP	32 Kbytes	1.5 Kbytes	PLQP0032GB-A]	
R5F21262SNXXXFP	8 Kbytes	512 bytes	PLQP0032GB-A	N version	Factory
R5F21264SNXXXFP	16 Kbytes	1 Kbyte	PLQP0032GB-A]	programming
R5F21265SNXXXFP	24 Kbytes	1.5 Kbytes	PLQP0032GB-A]	product ⁽¹⁾
R5F21266SNXXXFP	32 Kbytes	1.5 Kbytes	PLQP0032GB-A		
R5F21262SDXXXFP	8 Kbytes	512 bytes	PLQP0032GB-A	D version	
R5F21264SDXXXFP	16 Kbytes	1 Kbyte	PLQP0032GB-A]	
R5F21265SDXXXFP	24 Kbytes	1.5 Kbytes	PLQP0032GB-A		
R5F21266SDXXXFP	32 Kbytes	1.5 Kbytes	PLQP0032GB-A]	
R5F21264JXXXFP	16 Kbytes	1 Kbyte	PLQP0032GB-A	J version	
R5F21266JXXXFP	32 Kbytes	1.5 Kbytes	PLQP0032GB-A		
R5F21264KXXXFP	16 Kbytes	1 Kbyte	PLQP0032GB-A	K version	
R5F21266KXXXFP	32 Kbytes	1.5 Kbytes	PLQP0032GB-A	<u> </u>	

NOTE:

1. The user ROM is programmed before shipment.

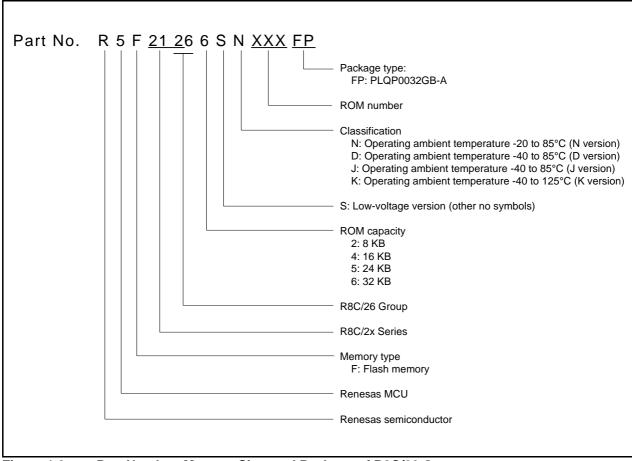


Figure 1.2 Part Number, Memory Size, and Package of R8C/26 Group

Table 1.4 **Product Information for R8C/27 Group**

Current of Sep. 2008

	ROM (Capacity	RAM			
Part No.	Program ROM	Data flash	Capacity	Package Type	Re	marks
R5F21272SNFP	8 Kbytes	1 Kbyte x 2	512 bytes	PLQP0032GB-A	N version	
R5F21274SNFP	16 Kbytes	1 Kbyte × 2	1 Kbyte	PLQP0032GB-A		
R5F21275SNFP	24 Kbytes	1 Kbyte × 2	1.5 Kbytes	PLQP0032GB-A		
R5F21276SNFP	32 Kbytes	1 Kbyte × 2	1.5 Kbytes	PLQP0032GB-A		
R5F21272SDFP	8 Kbytes	1 Kbyte × 2	512 bytes	PLQP0032GB-A	D version	
R5F21274SDFP	16 Kbytes	1 Kbyte × 2	1 Kbyte	PLQP0032GB-A		
R5F21275SDFP	24 Kbytes	1 Kbyte × 2	1.5 Kbytes	PLQP0032GB-A		
R5F21276SDFP	32 Kbytes	1 Kbyte × 2	1.5 Kbytes	PLQP0032GB-A		
R5F21274JFP	16 Kbytes	1 Kbyte × 2	1 Kbyte	PLQP0032GB-A	J version	
R5F21276JFP	32 Kbytes	1 Kbyte × 2	1.5 Kbytes	PLQP0032GB-A		
R5F21274KFP	16 Kbytes	1 Kbyte × 2	1 Kbyte	PLQP0032GB-A	K version	
R5F21276KFP	32 Kbytes	1 Kbyte × 2	1.5 Kbytes	PLQP0032GB-A		
R5F21272SNXXXFP	8 Kbytes	1 Kbyte × 2	512 bytes	PLQP0032GB-A	N version	Factory
R5F21274SNXXXFP	16 Kbytes	1 Kbyte × 2	1 Kbyte	PLQP0032GB-A		programming
R5F21275SNXXXFP	24 Kbytes	1 Kbyte × 2	1.5 Kbytes	PLQP0032GB-A		product ⁽¹⁾
R5F21276SNXXXFP	32 Kbytes	1 Kbyte × 2	1.5 Kbytes	PLQP0032GB-A		
R5F21272SDXXXFP	8 Kbytes	1 Kbyte × 2	512 bytes	PLQP0032GB-A	D version	
R5F21274SDXXXFP	16 Kbytes	1 Kbyte × 2	1 Kbyte	PLQP0032GB-A		
R5F21275SDXXXFP	24 Kbytes	1 Kbyte × 2	1.5 Kbytes	PLQP0032GB-A		
R5F21276SDXXXFP	32 Kbytes	1 Kbyte × 2	1.5 Kbytes	PLQP0032GB-A		
R5F21274JXXXFP	16 Kbytes	1 Kbyte × 2	1 Kbyte	PLQP0032GB-A	J version	
R5F21276JXXXFP	32 Kbytes	1 Kbyte x 2	1.5 Kbytes	PLQP0032GB-A		
R5F21274KXXXFP	16 Kbytes	1 Kbyte x 2	1 Kbyte	PLQP0032GB-A	K version]
R5F21276KXXXFP	32 Kbytes	1 Kbyte x 2	1.5 Kbytes	PLQP0032GB-A		

^{1.} The user ROM is programmed before shipment.

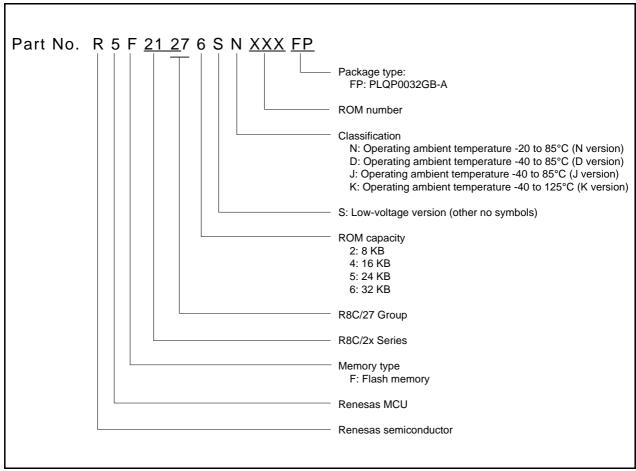


Figure 1.3 Part Number, Memory Size, and Package of R8C/27 Group

1.5 Pin Assignments

Figure 1.4 shows Pin Assignments (Top View).

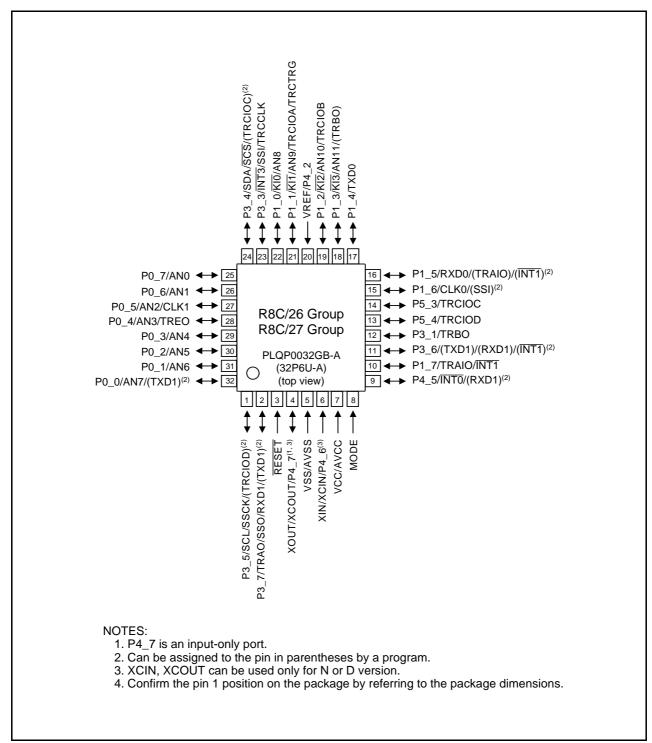


Figure 1.4 Pin Assignments (Top View)

1.6 Pin Functions

Table 1.5 lists Pin Functions.

Table 1.5 Pin Functions

Туре	Symbol	I/O Type	Description
Power supply input	VCC, VSS	I	Apply 2.2 to 5.5 V (J, K version are 2.7 to 5.5 V) to the VCC pin. Apply 0 V to the VSS pin.
Analog power supply input	AVCC, AVSS	I	Power supply for the A/D converter. Connect a capacitor between AVCC and AVSS.
Reset input	RESET	I	Input "L" on this pin resets the MCU.
MODE	MODE	I	Connect this pin to VCC via a resistor.
XIN clock input	XIN	I	These pins are provided for XIN clock generation circuit I/O. Connect a ceramic resonator or a crystal oscillator between the
XIN clock output	XOUT	0	XIN and XOUT pins. To use an external clock, input it to the XIN pin and leave the XOUT pin open.
XCIN clock input (N, D version)	XCIN	I	These pins are provided for XCIN clock generation circuit I/O. Connect a crystal oscillator between the XCIN and XCOUT
XCIN clock output (N, D version)	XCOUT	0	pins. To use an external clock, input it to the XCIN pin and leave the XCOUT pin open.
INT interrupt input	INTO, INT1, INT3	I	INT interrupt input pins
Key input interrupt	KIO to KI3	I	Key input interrupt input pins
Timer RA	TRAO	0	Timer RA output pin
	TRAIO	I/O	Timer RA I/O pin
Timer RB	TRBO	0	Timer RB output pin
Timer RC	TRCCLK	I	External clock input pin
	TRCTRG	I	External trigger input pin
	TRCIOA, TRCIOB, TRCIOC, TRCIOD	I/O	Sharing output-compare output / input-capture input / PWM / PWM2 output pins
Timer RE	TREO	0	Timer RE output pin
Serial interface	CLK0, CLK1	I/O	Clock I/O pin
	RXD0, RXD1	I	Receive data input pin
	TXD0, TXD1	0	Transmit data output pin
I ² C bus interface	SCL	I/O	Clock I/O pin
	SDA	I/O	Data I/O pin
Clock synchronous	SSI	I/O	Data I/O pin
serial I/O with chip	SCS	I/O	Chip-select signal I/O pin
select	SSCK	I/O	Clock I/O pin
	SSO	I/O	Data I/O pin
Reference voltage input	VREF	I	Reference voltage input pin to A/D converter
A/D converter	AN0 to AN11	I	Analog input pins to A/D converter
I/O port	P0_0 to P0_7, P1_0 to P1_7, P3_1, P3_3 to P3_7, P4_5, P5_3, P5_4	I/O	CMOS I/O ports. Each port has an I/O select direction register, allowing each pin in the port to be directed for input or output individually. Any port set to input can be set to use a pull-up resistor or not by a program. P1_0 to P1_7 also function as LED drive ports (N, D version).
Input port	P4_2, P4_6, P4_7	I	Input-only ports
			1

I: Input

O: Output

I/O: Input and output



Table 1.6 Pin Name Information by Pin Number

				I/O Pin I	Functions for o	of Peripheral Mo	dules	
Pin Number	Control Pin	Port	Interrupt	Timer	Serial Interface	Clock Synchronous Serial I/O with Chip Select	I ² C bus Interface	A/D Converter
1		P3_5		(TRCIOD) ⁽¹⁾		SSCK	SCL	
2		P3_7		TRAO	RXD1/ (TXD1) ^(1, 3)	SSO		
3	RESET							
4	XOUT/XCOUT ⁽²⁾	P4_7						
5	VSS/AVSS							
6	XIN/XCIN(2)	P4_6						
7	VCC/AVCC							
8	MODE							
9		P4_5	INT0		(RXD1) ^(1, 3)			
10		P1_7	INT1	TRAIO				
11		P3_6	(INT1) ⁽¹⁾		(TXD1)/ (RXD1) ^(1, 3)			
12		P3_1		TRBO				
13		P5_4		TRCIOD				
14		P5_3		TRCIOC				
15		P1_6			CLK0	(SSI) ⁽¹⁾		
16		P1_5	(INT1)(1)	(TRAIO) ⁽¹⁾	RXD0			
17		P1_4			TXD0			
18		P1_3	KI3	(TRBO)				AN11
19		P1_2	KI2	TRCIOB				AN10
20	VRFF	P4_2						
21		P1_1	KI1	TRCIOA/ TRCTRG				AN9
22		P1_0	KI0					AN8
23		P3_3	ĪNT3	TRCCLK		SSI		
24		P3_4		(TRCIOC) ⁽¹⁾		SCS	SDA	
25		P0_7						AN0
26		P0_6						AN1
27		P0_5			CLK1			AN2
28		P0_4		TREO				AN3
29		P0_3						AN4
30		P0_2						AN5
31		P0_1						AN6
32		P0_0			(TXD1) ^(1, 3)			AN7

- 1. This can be assigned to the pin in parentheses by a program.
- 2. XCIN, XCOUT can be used only for N or D version.
- 3. For the combination of using pins TXD1 and RXD1, refer to **Figure 15.7 Registers PINSR1 and PMR** of Hardware Manual (REJ09B0278).

2. **Central Processing Unit (CPU)**

Figure 2.1 shows the CPU Registers. The CPU contains 13 registers. R0, R1, R2, R3, A0, A1, and FB configure a register bank. There are two sets of register bank.

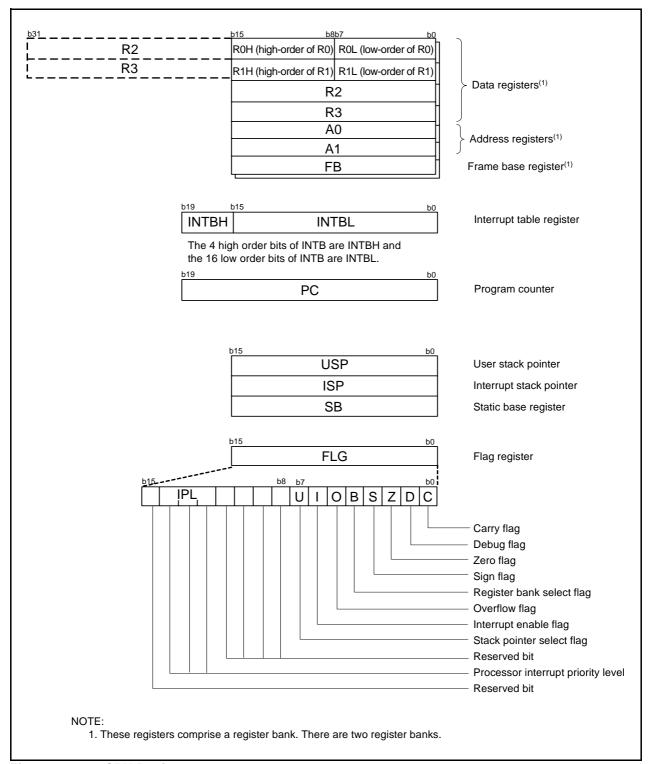


Figure 2.1 **CPU Registers**

2.1 Data Registers (R0, R1, R2, and R3)

R0 is a 16-bit register for transfer, arithmetic, and logic operations. The same applies to R1 to R3. R0 can be split into high-order bits (R0H) and low-order bits (R0L) to be used separately as 8-bit data registers. R1H and R1L are analogous to R0H and R0L. R2 can be combined with R0 and used as a 32-bit data register (R2R0). R3R1 is analogous to R2R0.

2.2 Address Registers (A0 and A1)

A0 is a 16-bit register for address register indirect addressing and address register relative addressing. It is also used for transfer, arithmetic, and logic operations. A1 is analogous to A0. A1 can be combined with A0 to be used as a 32-bit address register (A1A0).

2.3 Frame Base Register (FB)

FB is a 16-bit register for FB relative addressing.

2.4 **Interrupt Table Register (INTB)**

INTB is a 20-bit register that indicates the start address of an interrupt vector table.

2.5 **Program Counter (PC)**

PC is 20 bits wide and indicates the address of the next instruction to be executed.

2.6 User Stack Pointer (USP) and Interrupt Stack Pointer (ISP)

The stack pointers (SP), USP, and ISP, are each 16 bits wide. The U flag of FLG is used to switch between USP and ISP.

2.7 Static Base Register (SB)

SB is a 16-bit register for SB relative addressing.

2.8 Flag Register (FLG)

FLG is an 11-bit register indicating the CPU state.

2.8.1 Carry Flag (C)

The C flag retains carry, borrow, or shift-out bits that have been generated by the arithmetic and logic unit.

2.8.2 Debug Flag (D)

The D flag is for debugging only. Set it to 0.

2.8.3 Zero Flag (Z)

The Z flag is set to 1 when an arithmetic operation results in 0; otherwise to 0.

2.8.4 Sign Flag (S)

The S flag is set to 1 when an arithmetic operation results in a negative value; otherwise to 0.

2.8.5 Register Bank Select Flag (B)

Register bank 0 is selected when the B flag is 0. Register bank 1 is selected when this flag is set to 1.

2.8.6 Overflow Flag (O)

The O flag is set to 1 when an operation results in an overflow; otherwise to 0.



2.8.7 Interrupt Enable Flag (I)

The I flag enables maskable interrupts.

Interrupt are disabled when the I flag is set to 0, and are enabled when the I flag is set to 1. The I flag is set to 0 when an interrupt request is acknowledged.

2.8.8 Stack Pointer Select Flag (U)

ISP is selected when the U flag is set to 0; USP is selected when the U flag is set to 1.

The U flag is set to 0 when a hardware interrupt request is acknowledged or the INT instruction of software interrupt numbers 0 to 31 is executed.

2.8.9 Processor Interrupt Priority Level (IPL)

IPL is 3 bits wide and assigns processor interrupt priority levels from level 0 to level 7. If a requested interrupt has higher priority than IPL, the interrupt is enabled.

2.8.10 Reserved Bit

If necessary, set to 0. When read, the content is undefined.

3. Memory

3.1 R8C/26 Group

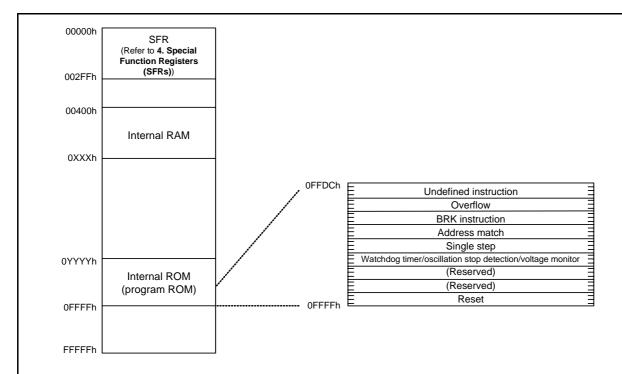
Figure 3.1 is a Memory Map of R8C/26 Group. The R8C/26 group has 1 Mbyte of address space from addresses 00000h to FFFFFh.

The internal ROM is allocated lower addresses, beginning with address 0FFFFh. For example, a 16-Kbyte internal ROM area is allocated addresses 0C000h to 0FFFFh.

The fixed interrupt vector table is allocated addresses 0FFDCh to 0FFFFh. They store the starting address of each interrupt routine.

The internal RAM is allocated higher addresses beginning with address 00400h. For example, a 1-Kbyte internal RAM area is allocated addresses 00400h to 007FFh. The internal RAM is used not only for storing data but also for calling subroutines and as stacks when interrupt requests are acknowledged.

Special function registers (SFRs) are allocated addresses 00000h to 002FFh. The peripheral function control registers are allocated here. All addresses within the SFR, which have nothing allocated are reserved for future use and cannot be accessed by users.



NOTE:

1. The blank regions are reserved. Do not access locations in these regions.

Part Number	Internal ROM		Internal RAM	
Fait Number	Size	Address 0YYYYh	Size	Address 0XXXXh
R5F21262SNFP, R5F21262SDFP,	8 Kbytes	0E000h	512 bytes	005FFh
R5F21262SNXXXFP, R5F21262SDXXXFP	o Royles	OLOGOTI	312 bytes	0031111
R5F21264SNFP, R5F21264SDFP,				
R5F21264JFP, R5F21264KFP,	16 Kbytes	0C000h	1 Kbyte	007FFh
R5F21264SNXXXFP, R5F21264SDXXXFP,	10 Rbytes	0000011	TROYLE	0071111
R5F21264JXXXFP, R5F21264KXXXFP				
R5F21265SNFP, R5F21265SDFP	24 Kbytes	0A000h	1.5 Kbytes	009FFh
R5F21265SNXXXFP, R5F21265SDXXXFP	24 Noytes	UAUUUII	1.5 Rbytes	0091111
R5F21266SNFP, R5F21266SDFP,				
R5F21266JFP, R5F21266KFP,	32 Kbytes	08000h	1.5 Kbytes	009FFh
R5F21266SNXXXFP, R5F21266SDXXXFP,	32 Royles	0000011	1.5 Rbytes	0031111
R5F21266JXXXFP, R5F21266KXXXFP				

Figure 3.1 Memory Map of R8C/26 Group

3.2 R8C/27 Group

Figure 3.2 is a Memory Map of R8C/27 Group. The R8C/27 group has 1 Mbyte of address space from addresses 00000h to FFFFFh.

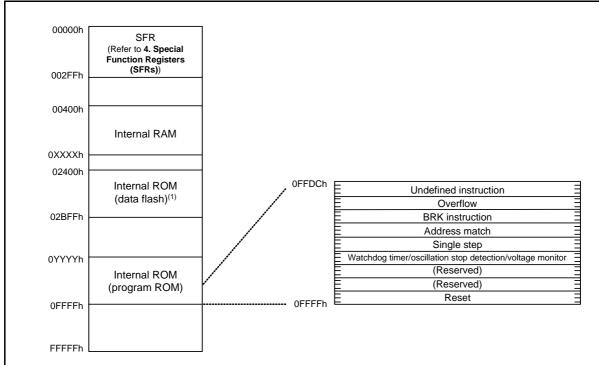
The internal ROM (program ROM) is allocated lower addresses, beginning with address 0FFFFh. For example, a 16-Kbyte internal ROM area is allocated addresses 0C000h to 0FFFFh.

The fixed interrupt vector table is allocated addresses 0FFDCh to 0FFFFh. They store the starting address of each interrupt routine.

The internal ROM (data flash) is allocated addresses 02400h to 02BFFh.

The internal RAM area is allocated higher addresses, beginning with address 00400h. For example, a 1-Kbyte internal RAM is allocated addresses 00400h to 007FFh. The internal RAM is used not only for storing data but also for calling subroutines and as stacks when interrupt requests are acknowledged.

Special function registers (SFRs) are allocated addresses 00000h to 002FFh. The peripheral function control registers are allocated here. All addresses within the SFR, which have nothing allocated are reserved for future use and cannot be accessed by users.



- 1. Data flash block A (1 Kbyte) and B (1 Kbyte) are shown.
- 2. The blank regions are reserved. Do not access locations in these regions.

Dord Mosek en	Internal ROM		Internal RAM	
Part Number	Size	Address 0YYYYh	Size	Address 0XXXXh
R5F21272SNFP, R5F21272SDFP,	0 Khyton	0E000h	E12 bytes	005FFh
R5F21272SNXXXFP, R5F21272SDXXXFP	8 Kbytes	000011	512 bytes	003FFII
R5F21274SNFP, R5F21274SDFP,				
R5F21274JFP, R5F21274KFP,	16 Khytos	0C000h	1 Kbyte	007FFh
R5F21274SNXXXFP, R5F21274SDXXXFP,	16 Kbytes	0000011	TRbyte	0077711
R5F21274JXXXFP, R5F21274KXXXFP				
R5F21275SNFP, R5F21275SDFP,	24 Kbytes	0A000h	1.5 Kbytes	009FFh
R5F21275SNXXXFP, R5F21275SDXXXFP	24 Kbytes	UAUUUII	1.5 Kbytes	009FFII
R5F21276SNFP, R5F21276SDFP,				
R5F21276JFP, R5F21276KFP,	32 Kbytes	08000h	1 E Khyton	009FFh
R5F21276SNXXXFP, R5F21276SDXXXFP,	32 Kbytes	0000011	1.5 Kbytes	009FFII
R5F21276JXXXFP, R5F21276KXXXFP				

Figure 3.2 Memory Map of R8C/27 Group

4. Special Function Registers (SFRs)

An SFR (special function register) is a control register for a peripheral function. Tables 4.1 to 4.7 list the special function registers.

Table 4.1 SFR Information (1)⁽¹⁾

Address	Register	Symbol	After reset
0000h			
0001h			
0002h			
0003h			
0004h	Processor Mode Register 0	PM0	00h
0005h	Processor Mode Register 1	PM1	00h
0006h	System Clock Control Register 0	CM0	01101000b
0007h	System Clock Control Register 1	CM1	00100000b
0008h			
0009h			
000Ah	Protect Register	PRCR	00h
000Bh			
000Ch	Oscillation Stop Detection Register	OCD	00000100b
000Dh	Watchdog Timer Reset Register	WDTR	XXh
000Eh	Watchdog Timer Start Register	WDTS	XXh
000Fh	Watchdog Timer Control Register	WDC	00X11111b
0010h	Address Match Interrupt Register 0	RMAD0	00h
0011h	1		00h
0012h	1		00h
0013h	Address Match Interrupt Enable Register	AIER	00h
0014h	Address Match Interrupt Register 1	RMAD1	00h
0015h	- · · · ·		00h
0016h	1		00h
0017h			
0018h			
0019h			
001Ah			
001Bh			
001Ch	Count Source Protection Mode Register	CSPR	00h
004Db			10000000b ⁽²⁾
001Dh 001Eh			
001Eh			
001Fh			
0021h 0022h			
	High Speed On Chip Oscillator Control Beginter C	ED AO	00h
0023h	High-Speed On-Chip Oscillator Control Register 0 High-Speed On-Chip Oscillator Control Register 1	FRA0	00h
0024h 0025h	High-Speed On-Chip Oscillator Control Register 1 High-Speed On-Chip Oscillator Control Register 2	FRA1 FRA2	When shipping 00h
0025h 0026h	riigh-speed On-Onip Oscillator Control Register 2	FRAZ	UUII
0026h			
	Clock Proceeder Penet Flog	CDCDE	00h
0028h	Clock Prescaler Reset Flag	CPSRF	00h
0029h	High-Speed On-Chip Oscillator Control Register 4(3)	FRA4	When shipping
002Ah	4	===	1
002Bh	High-Speed On-Chip Oscillator Control Register 6(3)	FRA6	When shipping
002Ch	High-Speed On-Chip Oscillator Control Register 7 ⁽³⁾	FRA7	When shipping
002Dh			
002Eh			
002Fh			

X: Undefined

- 1. The blank regions are reserved. Do not access locations in these regions.
- 2. The CSPROINI bit in the OFS register is set to 0.
- 3. In J, K version these regions are reserved. Do not access locations in these regions.

Table 4.2 SFR Information (2)⁽¹⁾

Address	Register	Symbol	After reset
0030h	-		
0031h	Voltage Detection Register 1 (2)	VCA1	00001000b
0032h	Voltage Detection Register 2 (2)	VCA2	• N, D version 00h ⁽³⁾
	Tomago Dotosion Hogisto. 2		00100000b ⁽⁴⁾
			• J, K version 00h ⁽⁷⁾
			01000000b ⁽⁸⁾
00001			010000006(0)
0033h			
0034h			
0035h	N 1	1,0046	N. D
0036h	Voltage Monitor 1 Circuit Control Register (5)	VW1C	• N, D version 00001000b
			• J, K version 0000X000b ⁽⁷⁾
			0100X001b ⁽⁸⁾
0037h	Voltage Monitor 2 Circuit Control Register (5)	VW2C	00h
0038h	Voltage Monitor 0 Circuit Control Register (6)	VW0C	0000X000b ⁽³⁾
			0100X001b ⁽⁴⁾
0039h			
	I	L	
003Fh			
0040h			
0041h			
0042h			
0043h			
0044h			
0045h			
0046h			
0047h	Timer RC Interrupt Control Register	TRCIC	XXXXX000b
0047H	Timer No Interrupt Control Negister	TROIC	70000000
0049h			
0043h	Timer RE Interrupt Control Register	TREIC	XXXXX000b
004An	Timer NE Interrupt Control Negister	TREIC	XXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXX
004Bh			
004CH	Key Input Interrupt Control Register	KUPIC	XXXXX000b
004Bh	A/D Conversion Interrupt Control Register	ADIC	XXXXX000b
004En		SSUIC/IICIC	XXXXX000b
	SSU/IIC bus Interrupt Control Register ⁽⁹⁾	33010/11010	**************************************
0050h	LIADTO Too a social latera and Control Descietos	COTIC	VVVVV000b
0051h	UARTO Transmit Interrupt Control Register	SOTIC	XXXXX000b
0052h	UARTO Receive Interrupt Control Register	SORIC	XXXXX000b
0053h	UART1 Transmit Interrupt Control Register	S1TIC	XXXXX000b
0054h	UART1 Receive Interrupt Control Register	S1RIC	XXXXX000b
0055h			Lyana a sa
0056h	Timer RA Interrupt Control Register	TRAIC	XXXXX000b
0057h			
0058h	Timer RB Interrupt Control Register	TRBIC	XXXXX000b
0059h	INT1 Interrupt Control Register	INT1IC	XX00X000b
005Ah	INT3 Interrupt Control Register	INT3IC	XX00X000b
005Bh			
005Ch	I I I I I I I I I I I I I I I I I I I		
005Dh	INT0 Interrupt Control Register	INTOIC	XX00X000b
005Eh			
005Fh			
0060h			
	1		
006Fh			
0070h			
	_		
007Fh			
X: Undefined			

- 1. The blank regions are reserved. Do not access locations in these regions.
- 2. (N, D version) Software reset, watchdog timer reset, voltage monitor 1 reset, or voltage monitor 2 reset do not affect this register. (J, K version) Software reset, watchdog timer reset, or voltage monitor 2 reset do not affect this register.
- 3. The LVD0ON bit in the OFS register is set to 1 and hardware reset.
- 4. Power-on reset, voltage monitor 0 reset or the LVD0ON bit in the OFS register is set to 0, and hardware reset.
- 5. (N, D version) Software reset, watchdog timer reset, voltage monitor 1 reset, or voltage monitor 2 reset do not affect b2 and b3. (J, K version) Software reset, watchdog timer reset, or voltage monitor 2 reset do not affect b2 and b3.
- 6. (N, D version) Software reset, watchdog timer reset, voltage monitor 1 reset, or voltage monitor 2 reset do not affect this register. (J, K version) These regions are reserved. Do not access locations in these regions.
- 7. The LVD1ON bit in the OFS register is set to 1 and hardware reset.
- 8. Power-on reset, voltage monitor 1 reset, or the LVD10N bit in the OFS register is set to 0 and hardware reset.
- 9. Selected by the IICSEL bit in the PMR register.



SFR Information (3)⁽¹⁾ Table 4.3

Address	Register	Symbol	After reset
0080h	1109,500		7
0081h			
0082h			
0083h			
0084h			
0085h			
0086h			
0087h			
0087H			
0089h			
0089h			
008Bh			
008Ch			
008Ch			
008Eh			
008Fh			
0090h			
0090H			
0091h			
0092h 0093h			
0093h 0094h			
0094h 0095h			
0095h			
0097h 0098h			
0098h			
009Ah			
009Bh			
009Ch			
009Dh			
009Eh			
009Fh		LIONED	
00A0h	UARTO Transmit/Receive Mode Register	U0MR	00h
00A1h	UARTO Bit Rate Register	U0BRG	XXh
00A2h	UART0 Transmit Buffer Register	U0TB	XXh
00A3h	LIANTO T	11000	XXh
00A4h	UART0 Transmit/Receive Control Register 0	U0C0	00001000b
00A5h	UART0 Transmit/Receive Control Register 1	U0C1	00000010b
00A6h	UART0 Receive Buffer Register	U0RB	XXh
00A7h			XXh
00A8h	UART1 Transmit/Receive Mode Register	U1MR	00h
00A9h	UART1 Bit Rate Register	U1BRG	XXh
00AAh	UART1 Transmit Buffer Register	U1TB	XXh
00ABh			XXh
00ACh	UART1 Transmit/Receive Control Register 0	U1C0	00001000b
00ADh	UART1 Transmit/Receive Control Register 1	U1C1	00000010b
00AEh	UART1 Receive Buffer Register	U1RB	XXh
00AFh			XXh
00B0h			1
00B1h			
00B2h			1
00B3h			
00B4h			
00B5h			
00B6h			
00B7h			
00B8h	SS Control Register H / IIC bus Control Register 1 ⁽²⁾	SSCRH / ICCR1	00h
00B9h	SS Control Register L / IIC bus Control Register 2 ⁽²⁾	SSCRL / ICCR2	01111101b
00BAh	SS Mode Register / IIC bus Mode Register ⁽²⁾	SSMR / ICMR	00011000b
00BBh	SS Enable Register / IIC bus Interrupt Enable Register ⁽²⁾	SSER / ICIER	00h
00BCh	SS Status Register / IIC bus Status Register ⁽²⁾	SSSR / ICSR	00h / 0000X000b
00BDh	SS Mode Register 2 / Slave Address Register ⁽²⁾	SSMR2 / SAR	00h
00BEh		SSTDR / ICDRT	FFh
	SS Transmit Data Register / IIC bus Transmit Data Register(2)		
00BFh X: Undefined	SS Receive Data Register / IIC bus Receive Data Register ⁽²⁾	SSRDR / ICDRR	FFh

X: Undefined

NOTES:

1. The blank regions are reserved. Do not access locations in these regions.
2. Selected by the IICSEL bit in the PMR register.

SFR Information (4)⁽¹⁾ Table 4.4

Address	Register	Symbol	After reset
00C0h	A/D Register	AD	XXh
00C1h			XXh
00C2h			
00C3h			
00C4h			
00C5h			
00C6h			
00C7h			
00C8h			
00C9h			
00CAh			
00CBh			
00CCh			
00CDh			
00CEh			
00CEn			
00D0h			
00D1h			
00D2h			
00D3h			
00D4h	A/D Control Register 2	ADCON2	00h
00D5h			
00D6h	A/D Control Register 0	ADCON0	00h
00D7h	A/D Control Register 1	ADCON1	00h
00D8h			
00D9h			
00DAh			
00DBh			
00DCh			
00DDh			
00DEh			
00DEh			
00E0h	Port P0 Register	P0	00h
	Port P4 Parister	P1	
00E1h	Port P1 Register		00h
00E2h	Port P0 Direction Register	PD0	00h
00E3h	Port P1 Direction Register	PD1	00h
00E4h			
00E5h	Port P3 Register	P3	00h
00E6h			
00E7h	Port P3 Direction Register	PD3	00h
00E8h	Port P4 Register	P4	00h
00E9h	Port P5 Register	P5	00h
00EAh	Port P4 Direction Register	PD4	00h
00EBh	Port P5 Direction Register	PD5	00h
00ECh		1	
00EDh		+	
00EEh		+	
00EFh		+	
00E111		+	
00F0H			
		<u> </u>	
00F2h			
00F3h			
00F4h			001
00F5h	Pin Select Register 1	PINSR1	00h
00F6h	Pin Select Register 2	PINSR2	00h
00F7h	Pin Select Register 3	PINSR3	00h
00F8h	Port Mode Register	PMR	00h
00F9h	External Input Enable Register	INTEN	00h
00FAh	INT Input Filter Select Register	INTF	00h
00FBh	Key Input Enable Register	KIEN	00h
00FCh	Pull-Up Control Register 0	PUR0	00h
00FDh	Pull-Up Control Register 1	PUR1	00h
00FEh	Port P1 Drive Capacity Control Register ⁽²⁾	P1DRR	00h

X: Undefined

- NOTES:

 1. The blank regions are reserved. Do not access locations in these regions.
 - 2. In J, K version these regions are reserved. Do not access locations in these regions.

Table 4.5 SFR Information (5)⁽¹⁾

Madess				
1010	Address	Register	Symbol	After reset
10109h	0100h	Timer RA Control Register	TRACR	00h
10109h	0101h	Timer RA I/O Control Register	TRAIOC	00h
10109h				
1014h				
0106h			TRAPRE	FFh
0106h	0104h	Timer RA Register	TRA	FFh
0107h LIN Control Register LINST 00h	0105h	5		
0107h		LINI Control Devictor	LINIOD	201-
0108h Timer RB Control Register TRBCR 00h			-	
0109h	0107h		LINST	00h
0109h	0108h	Timer RB Control Register	TRBCR	00h
010Ah				
O106h				
OTOCh				00h
OTOCh	010Bh	Timer RB Mode Register	TRBMR	00h
0100h	010Ch		TRRPRE	FFh
O10Eh				
0110h				
0110h	010Eh	Timer RB Primary Register	TRBPR	FFh
0110h	010Fh			
0111h				
0112h				
0115h	0111h			
0115h	0112h			
0114h				
0115h				
0116h				
0117h 0118h Timer RE Second Data Register / Counter Data Register TRESEC 00h 0118h Timer RE Minute Data Register / Compare Data Register TREMIN 00h 0117h Timer RE Hour Data Register / Compare Data Register TREWK 00h 0118h Timer RE Day of Week Data Register / TREWK 00h 0110h Timer RE Control Register 1 TRECR1 00h 0110h Timer RE Control Register 2 TRECR2 00h 011bh Timer RE Count Source Select Register TRECR2 00h 011bh Timer RC Gount Source Select Register TRCRR 00001000b 011Fh Timer RC Count Source Select Register TRCMR 011001000b 012bh Timer RC Count Source Select Register TRCMR 01001000b 012th Timer RC Count Source Select Register TRCCR1 00h 012th Timer RC Count Select Register T TRCCR1 00h 012th Timer RC Counter Register D TRCGR0 110001000b 0125h Timer RC General Register A TRCGRA FFh 012bh <td>0115h</td> <td></td> <td></td> <td></td>	0115h			
0117h 0118h Timer RE Second Data Register / Counter Data Register TRESEC 00h 0118h Timer RE Minute Data Register / Compare Data Register TREMIN 00h 0117h Timer RE Hour Data Register / Compare Data Register TREWK 00h 0118h Timer RE Day of Week Data Register / TREWK 00h 0110h Timer RE Control Register 1 TRECR1 00h 0110h Timer RE Control Register 2 TRECR2 00h 011bh Timer RE Count Source Select Register TRECR2 00h 011bh Timer RC Gount Source Select Register TRCRR 00001000b 011Fh Timer RC Count Source Select Register TRCMR 011001000b 012bh Timer RC Count Source Select Register TRCMR 01001000b 012th Timer RC Count Source Select Register TRCCR1 00h 012th Timer RC Count Select Register T TRCCR1 00h 012th Timer RC Counter Register D TRCGR0 110001000b 0125h Timer RC General Register A TRCGRA FFh 012bh <td>0116h</td> <td></td> <td></td> <td></td>	0116h			
O118h				
O119h			TDEOES	001
O11Ah	0118h		TRESEC	00h
O11Ah	0119h	Timer RE Minute Data Register / Compare Data Register	TREMIN	00h
011Bh Timer RE Day of Week Data Register(2) TREWK 00h 011Ch Timer RE Control Register 1 TRECR1 00h 011Dh Timer RE Control Register 2 TRECR2 00h 011Eh Timer RE Count Source Select Register TRECR2 00h 011Fh Timer RC Mode Register TRCMR 01001000b 012Dh Timer RC Mode Register 1 TRCCR1 00h 0122h Timer RC Control Register 1 TRCICR1 00h 0122h Timer RC Control Register 1 TRCICR1 00h 0122h Timer RC Status Register 1 TRCICR2 01110000b 0123h Timer RC Status Register 6 TRCIOR0 10001000b 0124h Timer RC I/O Control Register 0 TRCIOR0 10001000b 0125h Timer RC I/O Control Register 1 TRCIOR0 10001000b 0126h Timer RC Counter TRC 00h 0127h Timer RC General Register A TRCGRA FFh 0128h Timer RC General Register A TRCGRB FFh 0129h	011 A h		TREHR	00h
011Ch				
O11Dh	011Bh	Timer RE Day of Week Data Register ⁽²⁾	TREWK	00h
O11Dh	011Ch	Timer RE Control Register 1	TRECR1	00h
011Eh Timer RE Count Source Select Register TRECSR 00001000b 011Fh 011Fh Timer RC Mode Register TRCMR 01001000b 0120h Timer RC Control Register 1 TRCCR1 00h 0122h Timer RC Interrupt Enable Register TRCIER 01110000b 0123h Timer RC Interrupt Enable Register TRCSR 01110000b 0123h Timer RC Ivic Control Register 0 TRCIRR 0110000b 0124h Timer RC Ivic Control Register 0 TRCIOR0 10001000b 0125h Timer RC Counter TRC 00h 0126h Timer RC Counter TRC 00h 0127h 00h 00h 00h 0128h Timer RC General Register A TRCGRA FFh 0129h FFh FFh FFh 0129h Timer RC General Register B TRCGRB FFh 012Dh Timer RC General Register B TRCGRC FFh 012Dh Timer RC General Register B TRCGRD FFh 012Ph Timer RC General				
011Fh			-	
0120h Timer RC Mode Register TRCMR 010101000b 0121h Timer RC Control Register 1 TRCCR1 00h 0122h Timer RC Interrupt Enable Register TRCIER 01110000b 0123h Timer RC Interrupt Enable Register 0 TRCIER 01110000b 0124h Timer RC I/O Control Register 0 TRCIOR0 10001000b 0125h Timer RC V/O Control Register 1 TRCIOR1 10001000b 0126h Timer RC Gounter TRC 00h 0127h 00h 00h 00h 0128h Timer RC General Register A TRCGRA FFh 0129h Timer RC General Register B TRCGRB FFh 012Ah Timer RC General Register C TRCGRD FFh 012Dh Timer RC General Register D TRCGRD FFh 012Eh Timer RC General Register D TRCCR2 00011111b 013th Timer RC Control Register 2 TRCCR2 00011111b 013sh Timer RC Output Master Enable Register TRCOER 01111111b 0138		Timer RE Count Source Select Register	TRECSR	00001000b
1214	011Fh			
1214	0120h	Timer RC Mode Register	TRCMR	01001000b
10122h				
0123h Timer RC Status Register TRCSR 01110000b 0124h Timer RC I/O Control Register 0 TRCIOR0 10001000b 0125h Timer RC I/O Control Register 1 10001000b 10001000b 0126h Timer RC Gounter TRC 00h 0127h O0h 00h 00h 0128h Timer RC General Register A FFh 0129h Timer RC General Register B TRCGRB FFh 012Bh Timer RC General Register C TRCGRC FFh 012Dh Timer RC General Register D TRCGRD FFh 012Eh Timer RC General Register D TRCGRD FFh 012Fh Timer RC Control Register 2 TRCCR2 00011111b 013th Timer RC Digital Filter Function Select Register TRCDF 00h 0132h Timer RC Output Master Enable Register TRCOER 01111111b 0138h 0136h 0137h 0138h 0139h 0138h 0138h 0138h 0138h 0138h 0138h 0138h				
O124h	0122h	Timer RC Interrupt Enable Register	TRCIER	01110000b
O124h	0123h	Timer RC Status Register	TRCSR	01110000b
0125h Timer RC I/O Control Register 1 TRCIOR1 10001000b 0126h Timer RC Counter TRC 00h 0127h Timer RC General Register A TRCGRA FFh 0129h Timer RC General Register B TRCGRB FFh 0128h Timer RC General Register B TRCGRC FFh 0128h Timer RC General Register C TRCGRC FFh 012bh Timer RC General Register D TRCGRD FFh 012bh Timer RC General Register D TRCGRD FFh 012bh Timer RC Control Register 2 TRCCR2 00011111b 013th Timer RC Digital Filter Function Select Register TRCDF 00h 0132h Timer RC Output Master Enable Register TRCOER 01111111b 0133h 0134h 0135h 0136h 0137h 0138h 0136h 0137h 0138h 0137h 0138h 0138h 0130h 0130h 0130h 0130h 0132h 0130h 0130h 0130h <td></td> <td>Timor PC I/O Control Projector 0</td> <td></td> <td></td>		Timor PC I/O Control Projector 0		
0126h Timer RC Counter TRC 00h 0127h Timer RC General Register A TRCGRA FFh 0128h Timer RC General Register B TRCGRB FFh 012Ah Timer RC General Register B TRCGRB FFh 012Bh Timer RC General Register C TRCGRC FFh 012Dh Timer RC General Register D TRCGRD FFh 012Fh Timer RC Control Register 2 TRCCR2 00011111b 0130h Timer RC Digital Filter Function Select Register TRCDF 00h 0132h Timer RC Output Master Enable Register TRCOER 01111111b 0133h 0134h 0135h 0137h 0138h 0138h 0138h 0138h 013Ch 013Dh 013Ch 013Dh 013Eh 013Eh 013Eh 013Eh				
0127h 00h 0128h Timer RC General Register A TRCGRA FFh 0129h Timer RC General Register B TRCGRB FFh 012Bh Timer RC General Register C TRCGRC FFh 012Dh Timer RC General Register D TRCGRD FFh 012Fh Timer RC General Register D TRCCR2 00011111b 0130h Timer RC Control Register 2 TRCCR2 00011111b 0131h Timer RC Digital Filter Function Select Register TRCOER 01111111b 0133h Timer RC Output Master Enable Register TRCOER 01111111b 0133h 0134h 0135h 0136h 0137h 0138h 0136h 0137h 0138h 0130h 0130h 0130h 013Ch 013Ch 013Ch 013Ch 013Eh 013Eh 013Eh 013Eh				10001000b
0128h Timer RC General Register A TRCGRA FFh 0129h Timer RC General Register B TRCGRB FFh 012Ah Timer RC General Register B TRCGRB FFh 012Bh Timer RC General Register C TRCGRC FFh 012Dh Timer RC General Register D TRCGRD FFh 012Fh Timer RC Control Register 2 TRCCR2 00011111b 0131h Timer RC Digital Filter Function Select Register TRCDF 00h 0132h Timer RC Output Master Enable Register TRCOER 01111111b 0133h 0134h 0135h 0136h 0137h 0138h 0138h 0138h 0138h 0138h 0138h 0136h 013Ch 013Dh 013Ch 013Bh 013Bh 013Ch 013Bh 013Ch 013Eh TRCDER 01111111b 013Ch 013Ch	0126h	Timer RC Counter	TRC	00h
0128h Timer RC General Register A TRCGRA FFh 0129h Timer RC General Register B TRCGRB FFh 012Ah Timer RC General Register B TRCGRB FFh 012Bh Timer RC General Register C TRCGRC FFh 012Dh Timer RC General Register D TRCGRD FFh 012Fh Timer RC Control Register 2 TRCCR2 00011111b 0131h Timer RC Digital Filter Function Select Register TRCDF 00h 0132h Timer RC Output Master Enable Register TRCOER 01111111b 0133h 0134h 0135h 0136h 0137h 0138h 0138h 0138h 0138h 0138h 0138h 0136h 013Ch 013Dh 013Ch 013Bh 013Bh 013Ch 013Bh 013Ch 013Eh TRCDER 01111111b 013Ch 013Ch	0127h			00h
0129h FFh 012Ah Timer RC General Register B TRCGRB FFh 012Bh Timer RC General Register C TRCGRC FFh 012Ch Timer RC General Register C FFh FFh 012Eh Timer RC General Register D TRCGRD FFh 013Ph Timer RC Control Register 2 TRCCR2 00011111b 0131h Timer RC Digital Filter Function Select Register TRCDF 00h 0132h Timer RC Output Master Enable Register TRCOER 01111111b 0133h 0134h 0135h 0136h 0137h 0138h 0139h 0138h 013Bh 013Ch 013Ch 013Ch 013Dh 013Eh 013Eh 013Eh		Times DC Correct Desister A	TDOODA	* *
012Ah Timer RC General Register B TRCGRB FFh 012Bh Timer RC General Register C TRCGRC FFh 012Dh Timer RC General Register D TRCGRD FFh 012Fh Timer RC General Register D TRCGRD FFh 013Dh Timer RC Control Register 2 TRCCR2 00011111b 0131h Timer RC Digital Filter Function Select Register TRCDF 00h 0132h Timer RC Output Master Enable Register TRCOER 01111111b 0134h 0134h 0136h 0136h 0137h 0138h 0139h 0138h 0138h 0138h 013Ch 013Ch 013Dh 013Eh 013Eh 013Eh		Timer RC General Register A	TRUGRA	
012Bh FFh 012Ch Timer RC General Register C TRCGRC FFh 012Dh Timer RC General Register D TRCGRD FFh 012Fh Timer RC Control Register 2 TRCCR2 00011111b 0131h Timer RC Digital Filter Function Select Register TRCDF 00h 0132h Timer RC Output Master Enable Register TRCOER 01111111b 0133h 0134h 0135h 0136h 0137h 0138h 0139h 0139h 013Ah 013Bh 013Bh 013Ch 013Dh 013Dh 013Dh 013Dh 013Dh 013Eh 013Eh 013Eh	0129h			FFh
012Bh FFh 012Ch Timer RC General Register C TRCGRC FFh 012Dh Timer RC General Register D TRCGRD FFh 012Fh Timer RC Control Register 2 TRCCR2 00011111b 0131h Timer RC Digital Filter Function Select Register TRCDF 00h 0132h Timer RC Output Master Enable Register TRCOER 01111111b 0133h 0134h 0135h 0136h 0137h 0138h 0139h 0139h 013Ah 013Bh 013Bh 013Ch 013Dh 013Dh 013Dh 013Dh 013Dh 013Eh 013Eh 013Eh	012Ah	Timer RC General Register B	TRCGRB	FFh
012Ch Timer RC General Register C TRCGRC FFh 012Dh Timer RC General Register D TRCGRD FFh 012Fh Timer RC General Register D TRCGRD FFh 0130h Timer RC Control Register 2 TRCCR2 00011111b 0131h Timer RC Digital Filter Function Select Register TRCDF 00h 0132h Timer RC Output Master Enable Register TRCOER 01111111b 0133h 0134h 0135h 0136h 0137h 0138h 0139h 0139h 0138h 0139h 0130h 0130h 013Ch 013Dh 013Eh 013Eh				
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012Eh Timer RC General Register D TRCGRD FFh 012Fh Timer RC Control Register 2 TRCCR2 00011111b 0131h Timer RC Digital Filter Function Select Register TRCDF 00h 0132h Timer RC Output Master Enable Register TRCOER 01111111b 0133h 0134h 0135h 0136h 0137h 0138h 0139h 013Ah 0138h 013Ch 013Dh 013Dh 013Bh 013Ch 013Dh 013Eh 013Eh 013Eh		Timer RC General Register C	TRUGRU	
012Fh FFh 0130h Timer RC Control Register 2 TRCCR2 00011111b 0131h Timer RC Digital Filter Function Select Register TRCDF 00h 0132h Timer RC Output Master Enable Register TRCOER 01111111b 0133h 0134h 0134h 0135h 0136h 0137h 0138h 0139h 013Ah 013Bh 013Ch 013Dh 013Dh 013Bh 013Bh 013Bh 013Ch 013Bh 013Eh 013Eh 013Eh	012Dh			FFh
012Fh FFh 0130h Timer RC Control Register 2 TRCCR2 00011111b 0131h Timer RC Digital Filter Function Select Register TRCDF 00h 0132h Timer RC Output Master Enable Register TRCOER 01111111b 0133h 0134h 0134h 0135h 0136h 0137h 0138h 0139h 013Ah 013Bh 013Ch 013Dh 013Dh 013Bh 013Bh 013Bh 013Ch 013Bh 013Eh 013Eh 013Eh	012Fh	Timer RC General Register D	TRCGRD	FFh
0130h Timer RC Control Register 2 TRCCR2 00011111b 0131h Timer RC Digital Filter Function Select Register TRCDF 00h 0132h Timer RC Output Master Enable Register TRCOER 01111111b 0133h 0134h 0135h 0136h 0137h 0138h 0139h 0139h 0138h 013Bh 013Bh 013Bh 013Ch 013Dh 013Bh 013Bh 013Ch 013Bh 013Bh 013Bh 013Bh 013Ch 013Bh 013Bh 013Bh 013Ch 013Ch				
0131h Timer RC Digital Filter Function Select Register TRCDF 00h 0132h Timer RC Output Master Enable Register TRCOER 01111111b 0133h 0134h 0135h 0136h 0137h 0138h 0139h 0139h 0138h 0138h 0138h 0138h 0138h 0138h 0138h 013Ch 013Dh 013Dh 013Eh 013Eh 013Eh		T	TDOORS	
0132h Timer RC Output Master Enable Register TRCOER 01111111b 0133h 0134h 0135h 0135h 0136h 0136h 0137h 0138h 0139h 0139h 013Ah 013Ah 013Ah 013Ah 013Bh 013Ch 013Ch 013Dh 013Bh 013Bh 013Bh 013Ch 013Bh	0130h		TRCCR2	00011111b
0132h Timer RC Output Master Enable Register TRCOER 01111111b 0133h 0134h 0135h 0135h 0136h 0136h 0137h 0138h 0139h 0139h 013Ah 013Ah 013Ah 013Ah 013Bh 013Ch 013Ch 013Dh 013Bh 013Bh 013Bh 013Ch 013Bh	0131h	Timer RC Digital Filter Function Select Register	TRCDF	00h
0133h 0134h 0135h 0136h 0137h 0138h 0138h 0139h 0138h 0139h 013Ah 013Bh 013Ch 013Ch 013Ch 013Ch 013Ch				
0134h 0135h 0136h 0137h 0138h 0139h 0138h 0138h 0138h 0130h 0131h 0131h 0131h 0131h		Timo No Output Masion Emailo Nogiotoi	TROOLIN	011111112
0135h 0136h 0137h 0138h 0138h 0139h 013Ah 013Bh 013Ch 013Ch 013Dh				
0136h 0137h 0138h 0139h 013Ah 013Bh 013Ch 013Dh 013Eh	0134h			
0136h 0137h 0138h 0139h 013Ah 013Bh 013Ch 013Dh 013Eh	0135h			
0137h 0138h 0139h 013Ah 013Bh 013Ch 013Dh 013Eh				
0138h 0139h 013Ah 013Bh 013Ch 013Dh 013Eh				
0139h 013Ah 013Bh 013Ch 013Dh 013Eh				
0139h 013Ah 013Bh 013Ch 013Dh 013Eh	0138h			
013Ah 013Bh 013Ch 013Dh 013Eh				
013Bh				
013Ch 013Dh 013Eh				
013Dh 013Eh	013Bh			
013Dh 013Eh	013Ch			
013Eh				
013Fh			<u> </u>	
	013Fh			

- The blank regions are reserved. Do not access locations in these regions.
 In J, K version these regions are reserved. Do not access locations in these regions.

Table 4.6 SFR Information (6)⁽¹⁾

Address	Register	Symbol	After reset
0140h	-5	-,	
0141h			
0142h			
0143h			
0144h			
0145h			
0146h			
0147h			
0148h			
0149h			
014Ah			
014Bh			
014Ch			
014Dh			
014Eh			
014Fh			
0150h			
0150h			
0151h			
0152h			
0153fi 0154h			
0154H			
0155h			
0156fi 0157h			
0157h 0158h			
0159h			
015Ah 015Bh			
015Ch			
015Dh			
015Eh			
015Fh			
0160h			
0161h			
0162h			
0163h			
0164h			
0165h			
0166h			
0167h			
0168h			
0169h			
016Ah			
016Bh			
016Ch			
016Dh			
016Eh			
016Fh			
0170h			
0171h			
0172h			
0173h			
0174h			
0175h			
0176h			
0177h			
0178h			
0179h			
017Ah			
017Bh			
017Ch			
017Dh			
017Eh			
017Fh			
NOTE:			

NOTE

1. The blank regions are reserved. Do not access locations in these regions.

Table 4.7 SFR Information (7)⁽¹⁾

Address	Register	Symbol	After reset
0180h	, and the second	,	
0181h			
0182h			
0183h			
0184h			
0185h			
0186h			
0187h			
0188h			<u> </u>
0189h			
018Ah			
018Bh			<u> </u>
018Ch			
018Dh			
018Eh			
018Fh			
0190h			
0191h			+
0192h			+
0192h			+
0193h			+
0194n			+
0195h			
0196H			
0197h 0198h			1
0199h 019Ah			
019Bh			
019Ch			
019Dh			
019Eh			4
019Fh			
01A0h			
01A1h			
01A2h			
01A3h			
01A4h			
01A5h			
01A6h			
01A7h			
01A8h			
01A9h			
01AAh			
01ABh			
01ACh			
01ADh			
01AEh			
01AFh			
01B0h			
01B1h			
01B2h			
01B3h	Flash Memory Control Register 4	FMR4	01000000b
01B4h			
01B5h	Flash Memory Control Register 1	FMR1	1000000Xb
01B6h			
01B7h	Flash Memory Control Register 0	FMR0	00000001b
01B8h			
01B9h			1
01BAh			†
01BBh			
01BCh			
01BDh			+
01BEh			
01BFh			+
0.5111	<u>L</u>	l .	1

FFFFh Option Function Select Register OFS (Note 2)

X: Undefined

- 1. The blank regions are reserved. Do not access locations in these regions.
- 2. The OFS register cannot be changed by a program. Use a flash programmer to write to it.

Electrical Characteristics 5.

N, D Version 5.1

Table 5.1 **Absolute Maximum Ratings**

Symbol	Parameter	Condition	Rated Value	Unit
Vcc/AVcc	Supply voltage		-0.3 to 6.5	V
Vı	Input voltage		-0.3 to Vcc + 0.3	V
Vo	Output voltage		-0.3 to Vcc + 0.3	V
Pd	Power dissipation	Topr = 25°C	500	mW
Topr	Operating ambient temperature		-20 to 85 (N version) / -40 to 85 (D version)	°C
Tstg	Storage temperature		-65 to 150	°C

Table 5.2 **Recommended Operating Conditions**

Symbol		Parameter	Conditions Standard		Unit		
Symbol	ļ r	rarameter	Conditions	Min.	Тур.	Max.	Unit
Vcc/AVcc	Supply voltage			2.2	-	5.5	V
Vss/AVss	Supply voltage			-	0	_	V
ViH	Input "H" voltage			0.8 Vcc	-	Vcc	V
VIL	Input "L" voltage			0		0.2 Vcc	V
IOH(sum)	Peak sum output "H" current	Sum of all pins IOH(peak)		_	ı	-160	mA
IOH(sum)	Average sum output "H" current	Sum of all pins IOH(avg)		-	1	-80	mA
IOH(peak)	Peak output "H"	Except P1_0 to P1_7		-	I	-10	mA
	current	P1_0 to P1_7		=	=	-40	mA
IOH(avg)	Average output	Except P1_0 to P1_7		-		-5	mA
	"H" current	P1_0 to P1_7		-		-20	mA
IOL(sum)	Peak sum output "L" currents	Sum of all pins IOL(peak)		=	=	160	mA
IOL(sum)	Average sum output "L" currents	Sum of all pins IOL(avg)		-	_	80	mA
IOL(peak)	Peak output "L"	Except P1_0 to P1_7		-	-	10	mA
	currents	P1_0 to P1_7		-		40	mA
IOL(avg)	Average output	Except P1_0 to P1_7		-	ı	5	mA
	"L" current	P1_0 to P1_7		-		20	mA
f(XIN)	XIN clock input osc	cillation frequency	3.0 V ≤ Vcc ≤ 5.5 V	0	-	20	MHz
			2.7 V ≤ Vcc < 3.0 V	0	ı	10	MHz
			2.2 V ≤ Vcc < 2.7 V	0		5	MHz
f(XCIN)	XCIN clock input of	scillation frequency	2.2 V ≤ Vcc ≤ 5.5 V	0	-	70	kHz
_	System clock	OCD2 = 0	3.0 V ≤ Vcc ≤ 5.5 V	0	-	20	MHz
		XIN clock selected	2.7 V ≤ Vcc < 3.0 V	0		10	MHz
			2.2 V ≤ Vcc < 2.7 V	0		5	MHz
		OCD2 = 1 On-chip oscillator clock selected	FRA01 = 0 Low-speed on-chip oscillator clock selected	=	125	-	kHz
			FRA01 = 1 High-speed on-chip oscillator clock selected 3.0 V ≤ Vcc ≤ 5.5 V	_	-	20	MHz
			FRA01 = 1 High-speed on-chip oscillator clock selected 2.7 V ≤ Vcc ≤ 5.5 V	_	-	10	MHz
			FRA01 = 1 High-speed on-chip oscillator clock selected 2.2 V ≤ Vcc ≤ 5.5 V	_	-	5	MHz

- 1. Vcc = 2.2 to 5.5 V at Topr = -20 to 85°C (N version) / -40 to 85°C (D version), unless otherwise specified.
- 2. The average output current indicates the average value of current measured during 100 ms.



Table 5.3 A/I	Converter Converter	Characteristics
---------------	---------------------	-----------------

Symbol	Parameter	Conditions	Standard			Unit	
Symbol		raiametei	Conditions	Min.	Тур.	Max.	Offic
-	Resolution		Vref = AVCC	=	-	10	Bits
-	Absolute	10-bit mode	φAD = 10 MHz, Vref = AVCC = 5.0 V	=	-	±3	LSB
	accuracy	8-bit mode	φAD = 10 MHz, Vref = AVCC = 5.0 V	=	-	±2	LSB
		10-bit mode	φAD = 10 MHz, Vref = AVCC = 3.3 V	=	-	±5	LSB
		8-bit mode	φAD = 10 MHz, Vref = AVCC = 3.3 V	=	-	±2	LSB
		10-bit mode	φAD = 5 MHz, Vref = AVCC = 2.2 V	=	-	±5	LSB
		8-bit mode	φAD = 5 MHz, Vref = AVCC = 2.2 V	=	-	±2	LSB
Rladder	Resistor ladder		Vref = AVCC	10	-	40	kΩ
tconv	Conversion time	10-bit mode	φAD = 10 MHz, Vref = AVCC = 5.0 V	3.3	-	-	μS
		8-bit mode	φAD = 10 MHz, Vref = AVCC = 5.0 V	2.8	-	-	μS
Vref	Reference voltag	e		2.2	-	AVcc	V
VIA	Analog input volta	age ⁽²⁾		0	=	AVcc	V
-	A/D operating	Without sample and hold	Vref = AVCC = 2.7 to 5.5 V	0.25	-	10	MHz
	clock frequency	With sample and hold	Vref = AVCC = 2.7 to 5.5 V	1	-	10	MHz
		Without sample and hold	Vref = AVCC = 2.2 to 5.5 V	0.25	-	5	MHz
		With sample and hold	Vref = AVCC = 2.2 to 5.5 V	1	-	5	MHz

- 1. AVcc = 2.2 to 5.5 V at Topr = -20 to 85°C (N version) / -40 to 85°C (D version), unless otherwise specified.
- 2. When the analog input voltage is over the reference voltage, the A/D conversion result will be 3FFh in 10-bit mode and FFh in 8-bit mode.

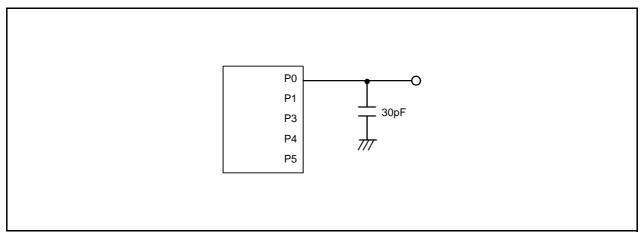


Figure 5.1 Ports P0, P1, and P3 to P5 Timing Measurement Circuit

Table 5.4 Flash Memory (Program ROM) Electrical Characteristics

Symbol	Parameter	Conditions		Unit		
Symbol	Farameter	Conditions	Min.	Тур.	Max.	Offic
=	Program/erase endurance ⁽²⁾	R8C/26 Group	100 ⁽³⁾	=	=	times
		R8C/27 Group	1,000(3)	=	_	times
=	Byte program time		=	50	400	μs
_	Block erase time		-	0.4	9	S
td(SR-SUS)	Time delay from suspend request until		-	_	97 + CPU clock	μS
	suspend				× 6 cycles	
_	Interval from erase start/restart until following suspend request		650	_	_	μ\$
=	Interval from program start/restart until following suspend request		0	=	-	ns
-	Time from suspend until program/erase restart		=	-	3 + CPU clock × 4 cycles	μS
_	Program, erase voltage		2.7	_	5.5	V
_	Read voltage		2.2	-	5.5	V
=	Program, erase temperature		0	-	60	°C
_	Data hold time ⁽⁷⁾	Ambient temperature = 55°C	20	_	-	year

- NOTES:

 1. Vcc = 2.7 to 5.5 V at Topr = 0 to 60°C, unless otherwise specified.
 - 2. Definition of programming/erasure endurance

The programming and erasure endurance is defined on a per-block basis.

If the programming and erasure endurance is n (n = 100 or 1,000), each block can be erased n times. For example, if 1,024 1-byte writes are performed to different addresses in block A, a 1 Kbyte block, and then the block is erased, the programming/erasure endurance still stands at one.

However, the same address must not be programmed more than once per erase operation (overwriting prohibited).

- 3. Endurance to guarantee all electrical characteristics after program and erase. (1 to Min. value can be guaranteed).
- 4. In a system that executes multiple programming operations, the actual erasure count can be reduced by writing to sequential addresses in turn so that as much of the block as possible is used up before performing an erase operation. For example, when programming groups of 16 bytes, the effective number of rewrites can be minimized by programming up to 128 groups before erasing them all in one operation. It is also advisable to retain data on the erasure endurance of each block and limit the number of erase operations to a certain number.
- 5. If an error occurs during block erase, attempt to execute the clear status register command, then execute the block erase command at least three times until the erase error does not occur.
- 6. Customers desiring program/erase failure rate information should contact their Renesas technical support representative.
- 7. The data hold time includes time that the power supply is off or the clock is not supplied.

Table 5.5 Flash Memory (Data flash Block A, Block B) Electrical Characteristics⁽⁴⁾

Symbol	Parameter	Conditions		Unit		
Symbol	Farameter	Conditions	Min.	Тур. Мах.		Offic
=	Program/erase endurance ⁽²⁾		10,000(3)	-	_	times
_	Byte program time (program/erase endurance ≤ 1,000 times)		-	50	400	μS
_	Byte program time (program/erase endurance > 1,000 times)		-	65	_	μS
_	Block erase time (program/erase endurance ≤ 1,000 times)		-	0.2	9	S
_	Block erase time (program/erase endurance > 1,000 times)		-	0.3	_	S
td(SR-SUS)	Time delay from suspend request until suspend		-	-	97 + CPU clock × 6 cycles	μS
_	Interval from erase start/restart until following suspend request		650	=	_	μS
_	Interval from program start/restart until following suspend request		0	-	_	ns
=	Time from suspend until program/erase restart		-	-	3 + CPU clock × 4 cycles	μS
=	Program, erase voltage		2.7	-	5.5	V
=	Read voltage		2.2	-	5.5	V
-	Program, erase temperature		-20 ⁽⁸⁾	_	85	°C
_	Data hold time ⁽⁹⁾	Ambient temperature = 55°C	20	_	_	year

- 1. Vcc = 2.7 to 5.5 V at Topr = -20 to 85°C (N version) / -40 to 85°C (D version), unless otherwise specified.
- 2. Definition of programming/erasure endurance
 - The programming and erasure endurance is defined on a per-block basis.

If the programming and erasure endurance is n (n = 10,000), each block can be erased n times. For example, if 1,024 1-byte writes are performed to different addresses in block A, a 1 Kbyte block, and then the block is erased, the programming/erasure endurance still stands at one.

However, the same address must not be programmed more than once per erase operation (overwriting prohibited).

- 3. Endurance to guarantee all electrical characteristics after program and erase. (1 to Min. value can be guaranteed).
- 4. Standard of block A and block B when program and erase endurance exceeds 1,000 times. Byte program time to 1,000 times is the same as that in program ROM.
- 5. In a system that executes multiple programming operations, the actual erasure count can be reduced by writing to sequential addresses in turn so that as much of the block as possible is used up before performing an erase operation. For example, when programming groups of 16 bytes, the effective number of rewrites can be minimized by programming up to 128 groups before erasing them all in one operation. In addition, averaging the erasure endurance between blocks A and B can further reduce the actual erasure endurance. It is also advisable to retain data on the erasure endurance of each block and limit the number of erase operations to a certain number.
- 6. If an error occurs during block erase, attempt to execute the clear status register command, then execute the block erase command at least three times until the erase error does not occur.
- 7. Customers desiring program/erase failure rate information should contact their Renesas technical support representative.
- 8. -40°C for D version.
- 9. The data hold time includes time that the power supply is off or the clock is not supplied.

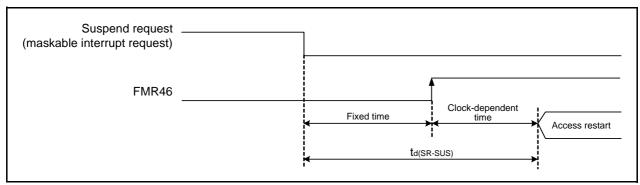


Figure 5.2 Time delay until Suspend

Table 5.6 **Voltage Detection 0 Circuit Electrical Characteristics**

Symbol	Parameter	Condition		Unit		
Syllibol	Falametei	Condition	Min.	Тур.	Max.	Offic
Vdet0	Voltage detection level		2.2	2.3	2.4	V
=	Voltage detection circuit self power consumption	VCA25 = 1, Vcc = 5.0 V	_	0.9	-	μΑ
td(E-A)	Waiting time until voltage detection circuit operation starts ⁽²⁾		-	=	300	μS
Vccmin	MCU operating voltage minimum value		2.2	=	-	V

- 1. The measurement condition is Vcc = 2.2 to 5.5 V and Topr = -20 to 85°C (N version) / -40 to 85°C (D version).
- 2. Necessary time until the voltage detection circuit operates when setting to 1 again after setting the VCA25 bit in the VCA2 register to 0.

Table 5.7 **Voltage Detection 1 Circuit Electrical Characteristics**

Symbol	Parameter	Condition		Unit		
Syllibol	Farameter	Condition	Min.	Тур.	Max.	Offic
Vdet1	Voltage detection level ⁽⁴⁾		2.70	2.85	3.00	V
-	Voltage monitor 1 interrupt request generation time ⁽²⁾		_	40	_	μS
=	Voltage detection circuit self power consumption	VCA26 = 1, Vcc = 5.0 V	-	0.6	-	μΑ
td(E-A)	Waiting time until voltage detection circuit operation starts ⁽³⁾		=	=	100	μS

- 1. The measurement condition is Vcc = 2.2 to 5.5 V and Topr = -20 to 85°C (N version) / -40 to 85°C (D version).
- 2. Time until the voltage monitor 1 interrupt request is generated after the voltage passes Vdet1.
- 3. Necessary time until the voltage detection circuit operates when setting to 1 again after setting the VCA26 bit in the VCA2 register to 0.
- 4. This parameter shows the voltage detection level when the power supply drops. The voltage detection level when the power supply rises is higher than the voltage detection level when the power supply drops by approximately 0.1 V.

Table 5.8 **Voltage Detection 2 Circuit Electrical Characteristics**

Symbol	Parameter	Condition		Unit		
Symbol	Parameter	Condition	Min.	Тур.	Max.	Unit
Vdet2	Voltage detection level		3.3	3.6	3.9	V
-	Voltage monitor 2 interrupt request generation time ⁽²⁾		_	40	_	μS
=	Voltage detection circuit self power consumption	VCA27 = 1, Vcc = 5.0 V	-	0.6	-	μΑ
td(E-A)	Waiting time until voltage detection circuit operation starts ⁽³⁾		II	=	100	μ\$

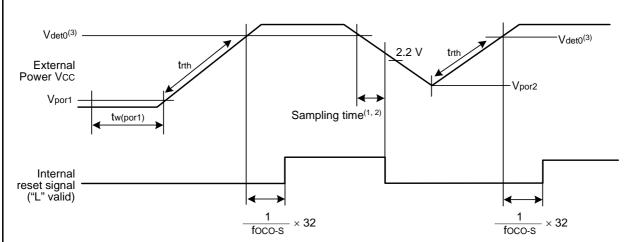
- 1. The measurement condition is Vcc = 2.2 to 5.5 V and Topr = -20 to 85°C (N version) / -40 to 85°C (D version).
- $2. \ \ \text{Time until the voltage monitor 2 interrupt request is generated after the voltage passes V_{det2}.}$
- 3. Necessary time until the voltage detection circuit operates after setting to 1 again after setting the VCA27 bit in the VCA2 register to 0.



Table 5.9	Power-on Reset Circuit.	Voltage Monitor 0 Reset Electrical Characteristics (3)
		Total go mornior o modern Endouncem on an action control

Symbol	Parameter	Condition		Unit		
	Faianetei	Condition	Min.	Тур.	Max.	Offic
Vpor1	Power-on reset valid voltage ⁽⁴⁾		_	_	0.1	V
Vpor2	Power-on reset or voltage monitor 0 reset valid voltage		0	_	Vdet0	V
trth	External power Vcc rise gradient(2)		20	_	_	mV/msec

- 1. The measurement condition is T_{OPT} = -20 to 85°C (N version) / -40 to 85°C (D version), unless otherwise specified.
- 2. This condition (external power Vcc rise gradient) does not apply if Vcc ≥ 1.0 V.
- 3. To use the power-on reset function, enable voltage monitor 0 reset by setting the LVD0ON bit in the OFS register to 0, the VW0C0 and VW0C6 bits in the VW0C register to 1 respectively, and the VCA25 bit in the VCA2 register to 1.
- 4. tw(por1) indicates the duration the external power Vcc must be held below the effective voltage (Vpor1) to enable a power on reset. When turning on the power for the first time, maintain tw(por1) for 30 s or more if -20°C ≤ Topr ≤ 85°C, maintain tw(por1) for 3,000 s or more if -40°C ≤ Topr < -20°C.</p>



- 1. When using the voltage monitor 0 digital filter, ensure that the voltage is within the MCU operation voltage range (2.2 V or above) during the sampling time.
- 2. The sampling clock can be selected. Refer to 6. Voltage Detection Circuit of Hardware Manual for details.
- 3. Vdeto indicates the voltage detection level of the voltage detection 0 circuit. Refer to 6. Voltage Detection Circuit of Hardware Manual for details.

Figure 5.3 Reset Circuit Electrical Characteristics

Table 5.10 High-speed On-Chip Oscillator Circuit Electrical Characteristics

Symbol	Parameter	Condition		I India		
		Condition	Min.	Тур.	Max.	Unit
fOCO40M	High-speed on-chip oscillator frequency temperature • supply voltage dependence	Vcc = 4.75 to 5.25 V $0^{\circ}C \leq T_{opr} \leq 60^{\circ}C^{(2)}$	39.2	40	40.8	MHz
		Vcc = 3.0 to 5.5 V -20°C \leq Topr \leq 85°C ⁽²⁾	38.8	40	41.2	MHz
		Vcc = 3.0 to 5.5 V -40°C \leq Topr \leq 85°C ⁽²⁾	38.4	40	41.6	MHz
		Vcc = 2.7 to 5.5 V -20°C \leq Topr \leq 85°C ⁽²⁾	38	40	42	MHz
		Vcc = 2.7 to 5.5 V -40°C \leq Topr \leq 85°C(2)	37.6	40	42.4	MHz
		Vcc = 2.2 to 5.5 V -20° C \leq Topr \leq 85 $^{\circ}$ C ⁽³⁾	35.2	40	44.8	MHz
		Vcc = 2.2 to 5.5 V -40°C \leq Topr \leq 85°C ⁽³⁾	34	40	46	MHz
		$Vcc = 5.0 V \pm 10\%$ -20°C \le Topr \le 85°C ⁽²⁾	38.8	40	40.8	MHz
		$Vcc = 5.0 V \pm 10\%$ -40°C \le Topr \le 85°C(2)	38.4	40	40.8	MHz
	High-speed on-chip oscillator frequency when correction value in FRA7 register is written to FRA1 register ⁽⁴⁾	Vcc = 5.0 V, Topr = 25°C	-	36.864	_	MHz
		Vcc = 3.0 to 5.5 V -20°C \le Topr \le 85°C	-3%	-	3%	%
_	Value in FRA1 register after reset		08h ⁽³⁾	-	F7h ⁽³⁾	-
_	Oscillation frequency adjustment unit of high- speed on-chip oscillator	Adjust FRA1 register (value after reset) to -1	-	+0.3	-	MHz
_	Oscillation stability time		_	10	100	μS
_	Self power consumption at oscillation	Vcc = 5.0 V, Topr = 25°C	-	400	_	μΑ

- 1. Vcc = 2.2 to 5.5 V, $T_{opr} = -20$ to $85^{\circ}C$ (N version) / -40 to $85^{\circ}C$ (D version), unless otherwise specified.
- 2. These standard values show when the FRA1 register value after reset is assumed.
- 3. These standard values show when the corrected value of the FRA6 register is written to the FRA1 register.
- 4. This enables the setting errors of bit rates such as 9600 bps and 38400 bps to be 0% when the serial interface is used in UART mode.

Table 5.11 Low-speed On-Chip Oscillator Circuit Electrical Characteristics

Symbol	Parameter	Condition		Unit		
Symbol	Farameter	Condition	Min.	Тур.	Max.	Offic
fOCO-S	Low-speed on-chip oscillator frequency		30	125	250	kHz
_	Oscillation stability time		-	10	100	μS
_	Self power consumption at oscillation	Vcc = 5.0 V, Topr = 25°C	-	15	-	μА

NOTE:

1. Vcc = 2.2 to 5.5 V, $T_{opr} = -20$ to $85^{\circ}C$ (N version) / -40 to $85^{\circ}C$ (D version), unless otherwise specified.

Table 5.12 Power Supply Circuit Timing Characteristics

Svmbol	Parameter	Condition	Standard			Unit
Syllibol	Falametei	Condition	Min.	Тур.	Max.	Offic
td(P-R)	Time for internal power supply stabilization during power-on ⁽²⁾		1	=	2000	μS
td(R-S)	STOP exit time ⁽³⁾		=	=	150	μS

- 1. The measurement condition is Vcc = 2.2 to 5.5 V and Topr = 25°C.
- 2. Waiting time until the internal power supply generation circuit stabilizes during power-on.
- 3. Time until system clock supply starts after the interrupt is acknowledged to exit stop mode.



Table 5.13 Timing Requirements of Clock Synchronous Serial I/O with Chip Select(1)

Cumbal	Parameter SSCK clock cycle time		Conditions		Unit		
Symbol				Min.	Тур.	Max.	1
tsucyc				4	-	=	tcyc(2)
tHI	SSCK clock "H" width			0.4	_	0.6	tsucyc
tLO	SSCK clock "L" width			0.4	-	0.6	tsucyc
trise	SSCK clock rising	Master		=	-	1	tcyc(2)
	time	Slave		-	-	1	μS
tFALL	SSCK clock falling time	Master		=	=	1	tcyc(2)
		Slave		-	-	1	μS
tsu	SSO, SSI data input setup time			100	-	=	ns
tH	SSO, SSI data input hold time			1	=	=	tcyc(2)
tLEAD	SCS setup time	Slave		1tcyc + 50	-	-	ns
tLAG	SCS hold time	Slave		1tcyc + 50	_	_	ns
top	SSO, SSI data output delay time			-	-	1	tcyc(2)
tsa	SSI slave access time		2.7 V ≤ Vcc ≤ 5.5 V	-	_	1.5tcyc + 100	ns
			2.2 V ≤ Vcc < 2.7 V	-	_	1.5tcyc + 200	ns
tor	SSI slave out open time		2.7 V ≤ Vcc ≤ 5.5 V	-	=	1.5tcyc + 100	ns
			2.2 V ≤ Vcc < 2.7 V	-	_	1.5tcyc + 200	ns

^{1.} Vcc = 2.2 to 5.5 V, Vss = 0 V at Topr = -20 to $85^{\circ}C$ (N version) / -40 to $85^{\circ}C$ (D version), unless otherwise specified. 2. 1tcyc = 1/f1(s)

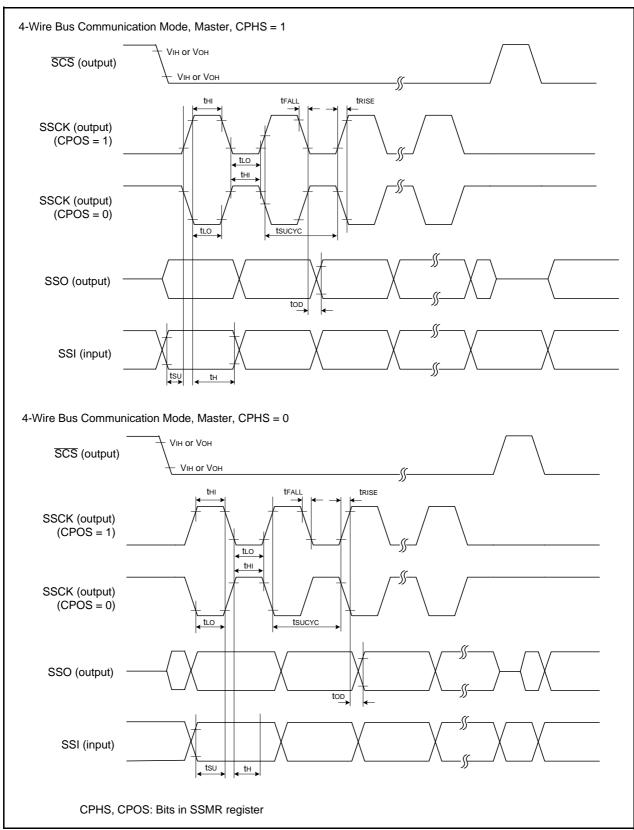


Figure 5.4 I/O Timing of Clock Synchronous Serial I/O with Chip Select (Master)

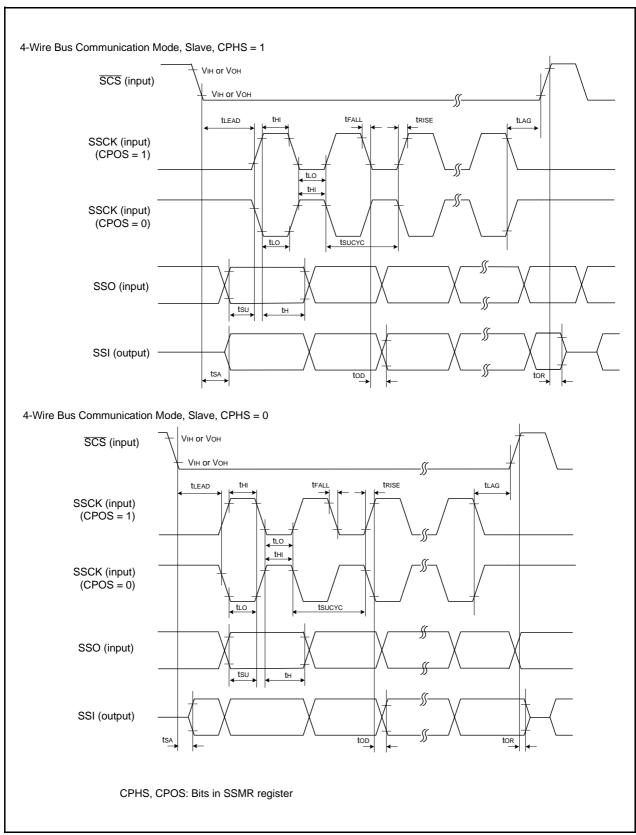


Figure 5.5 I/O Timing of Clock Synchronous Serial I/O with Chip Select (Slave)

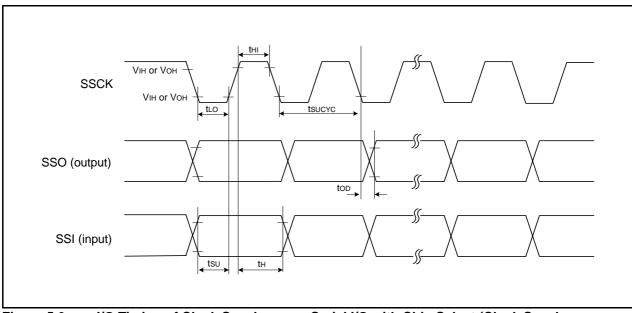


Figure 5.6 I/O Timing of Clock Synchronous Serial I/O with Chip Select (Clock Synchronous Communication Mode)

Table 5.14 Timing Requirements of I²C bus Interface⁽¹⁾

Symbol	Parameter	Condition	Standard			Unit	
Syllibol	Farameter	Condition	Min.	Тур.	Max.		
tscl	SCL input cycle time		12tcyc + 600 ⁽²⁾	-	_	ns	
tsclh	SCL input "H" width		3tcyc + 300 ⁽²⁾	=	-	ns	
tscll	SCL input "L" width		5tcyc + 500 ⁽²⁾	=	-	ns	
tsf	SCL, SDA input fall time		-	-	300	ns	
tsp	SCL, SDA input spike pulse rejection time		-	-	1tcyc(2)	ns	
tBUF	SDA input bus-free time		5tcyc(2)	-	-	ns	
tstah	Start condition input hold time		3tcyc(2)	=	-	ns	
tstas	Retransmit start condition input setup time		3tcyc(2)	=	-	ns	
tstop	Stop condition input setup time		3tcyc(2)	-	-	ns	
tsdas	Data input setup time		1tcyc + 20 ⁽²⁾	-	-	ns	
tsdah	Data input hold time		0	-	-	ns	

- 1. Vcc = 2.2 to 5.5 V, Vss = 0 V and $T_{opr} = -20$ to $85^{\circ}C$ (N version) / -40 to $85^{\circ}C$ (D version), unless otherwise specified.
- 2. 1tcyc = 1/f1(s)

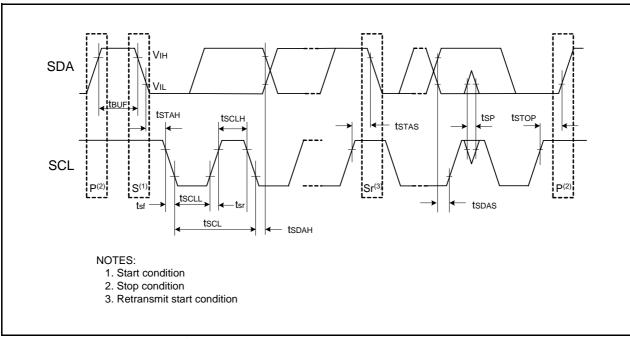


Figure 5.7 I/O Timing of I²C bus Interface

Table 5.15 Electrical Characteristics (1) [Vcc = 5 V]

Symbol	Po	rameter	Condition	-n	S	tandard		Unit
Symbol	Pai	rameter			Min.	Тур.	Max.	Onit
Vон	Output "H" voltage	Except P1_0 to P1_7,	Iон = −5 mA		Vcc - 2.0	_	Vcc	V
		XOUT	Іон = -200 μА		Vcc - 0.5	_	Vcc	V
		P1_0 to P1_7	Drive capacity HIGH	Iон = -20 mA	Vcc - 2.0	_	Vcc	V
			Drive capacity LOW	Iон = -5 mA	Vcc - 2.0	_	Vcc	V
		XOUT	Drive capacity HIGH	Iон = -1 mA	Vcc - 2.0	_	Vcc	V
			Drive capacity LOW	Ιοн = -500 μΑ	Vcc - 2.0	_	Vcc	V
Vol	Output "L" voltage	Except P1_0 to P1_7,	IoL = 5 mA		_	_	2.0	V
		XOUT	IoL = 200 μA		-	-	0.45	V
		P1_0 to P1_7	Drive capacity HIGH	IoL = 20 mA	-	-	2.0	V
			Drive capacity LOW	IoL = 5 mA	-	-	2.0	V
		XOUT	Drive capacity HIGH	IoL = 1 mA	-	-	2.0	V
			Drive capacity LOW	IOL = 500 μA	-	-	2.0	V
VT+-VT-	Hysteresis	INTO, INT1, INT3, KIO, KI1, KI2, KI3, TRAIO, RXDO, RXD1, CLK0, CLK1, SSI, SCL, SDA, SSO			0.1	0.5	-	V
		RESET			0.1	1.0	-	V
lін	Input "H" current	<u> </u>	VI = 5 V, Vcc = 5 V		_	_	5.0	μА
lıL	Input "L" current		VI = 0 V, Vcc = 5 V		_	_	-5.0	μA
RPULLUP	Pull-up resistance		VI = 0 V, Vcc = 5 V		30	50	167	kΩ
RfXIN	Feedback resistance	XIN			_	1.0	-	ΜΩ
RfXCIN	Feedback resistance	XCIN			-	18	-	МΩ
VRAM	RAM hold voltage	•	During stop mode		1.8	_	-	V

^{1.} Vcc = 4.2 to 5.5 V at Topr = -20 to $85^{\circ}C$ (N version) / -40 to $85^{\circ}C$ (D version), f(XIN) = 20 MHz, unless otherwise specified.

Table 5.16 Electrical Characteristics (2) [Vcc = 5 V] (Topr = -20 to 85°C (N version) / -40 to 85°C (D version), unless otherwise specified.)

Symbol	Parameter		Condition	Standard			Unit
Syllibol	Faiametei		Condition	Min.	Тур.	Max.	Offic
Icc	Power supply current (Vcc = 3.3 to 5.5 V) Single-chip mode, output pins are open,	High-speed clock mode	XIN = 20 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz No division	=	10	17	mA
	other pins are Vss		XIN = 16 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz No division	-	9	15	mA
		H	XIN = 10 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz No division	-	6	_	mA
			XIN = 20 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8	-	5	_	mA
			XIN = 16 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8	-	4	-	mA
			XIN = 10 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8	-	2.5	-	mA
		High-speed on-chip oscillator mode	XIN clock off High-speed on-chip oscillator on fOCO = 20 MHz Low-speed on-chip oscillator on = 125 kHz No division	_	10	15	mA
			XIN clock off High-speed on-chip oscillator on fOCO = 20 MHz Low-speed on-chip oscillator on = 125 kHz Divide-by-8	_	4	_	mA
			XIN clock off High-speed on-chip oscillator on fOCO = 10 MHz Low-speed on-chip oscillator on = 125 kHz No division	_	5.5	10	mA
			XIN clock off High-speed on-chip oscillator on fOCO = 10 MHz Low-speed on-chip oscillator on = 125 kHz Divide-by-8	=	2.5	=	mA
		Low-speed on-chip oscillator mode	XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8, FMR47 = 1	-	130	300	μА
		Low-speed clock mode	XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz FMR47 = 1	-	130	300	μА
			XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz Program operation on RAM Flash memory off, FMSTP = 1	_	30	_	μА

Table 5.17 Electrical Characteristics (3) [Vcc = 5 V] (Topr = -20 to 85°C (N version) / -40 to 85°C (D version), unless otherwise specified.)

Symbol	Parameter		Condition	;	Standar	d	Unit
Syllibol	Farameter		Condition	Min.	Тур.	Max.	Ullit
Icc	Power supply current (Vcc = 3.3 to 5.5 V) Single-chip mode, output pins are open, other pins are Vss	Wait mode	XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz While a WAIT instruction is executed Peripheral clock operation VCA27 = VCA26 = VCA25 = 0 VCA20 = 1	-	25	75	μА
			XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz While a WAIT instruction is executed Peripheral clock off VCA27 = VCA26 = VCA25 = 0 VCA20 = 1	_	23	60	μА
			XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz (high drive) While a WAIT instruction is executed VCA27 = VCA26 = VCA25 = 0 VCA20 = 1	_	4.0	-	μА
			XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz (low drive) While a WAIT instruction is executed VCA27 = VCA26 = VCA25 = 0 VCA20 = 1	_	2.2	-	μА
		Stop mode	XIN clock off, Topr = 25°C High-speed on-chip oscillator off Low-speed on-chip oscillator off CM10 = 1 Peripheral clock off VCA27 = VCA26 = VCA25 = 0	_	0.8	3.0	μА
			XIN clock off, Topr = 85°C High-speed on-chip oscillator off Low-speed on-chip oscillator off CM10 = 1 Peripheral clock off VCA27 = VCA26 = VCA25 = 0	_	1.2	_	μА

Timing Requirements

(Unless Otherwise Specified: Vcc = 5 V, Vss = 0 V at Topr = 25°C) [Vcc = 5 V]

Table 5.18 XIN Input, XCIN Input

Symbol	Parameter	Stan	Unit		
Symbol	Falanielei		Max.	Offic	
tc(XIN)	XIN input cycle time	50	-	ns	
twh(xin)	XIN input "H" width	25	-	ns	
tWL(XIN)	XIN input "L" width	25	-	ns	
tc(XCIN)	XCIN input cycle time	14	=	μS	
twh(xcin)	XCIN input "H" width	7	Ī	μS	
tWL(XCIN)	XCIN input "L" width	7	=	μS	

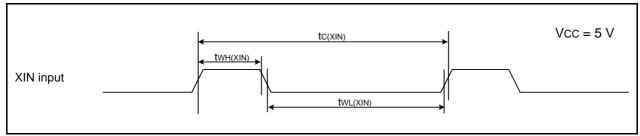


Figure 5.8 XIN Input and XCIN Input Timing Diagram when Vcc = 5 V

Table 5.19 TRAIO Input

Symbol	Parameter		Standard		
Symbol	raidilletei	Min.	Max.	Unit	
tc(TRAIO)	TRAIO input cycle time	100	=	ns	
twh(traio)	TRAIO input "H" width	40	=	ns	
twl(traio)	TRAIO input "L" width	40	=	ns	

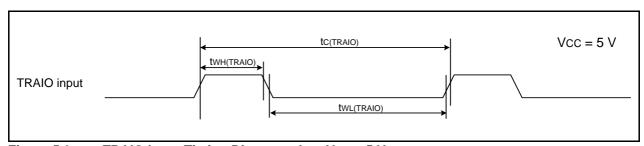


Figure 5.9 TRAIO Input Timing Diagram when Vcc = 5 V

Table 5.20 Serial Interface

Symbol	Parameter	Stan	Unit	
Symbol	Faidilletei	Min.	Max.	Offic
tc(CK)	CLKi input cycle time	200	=	ns
tW(CKH)	CLKi input "H" width	100	-	ns
tW(CKL)	CLKi input "L" width	100	-	ns
td(C-Q)	TXDi output delay time	-	50	ns
th(C-Q)	TXDi hold time	0	-	ns
tsu(D-C)	RXDi input setup time	50	=	ns
th(C-D)	RXDi input hold time	90	-	ns

i = 0 or 1

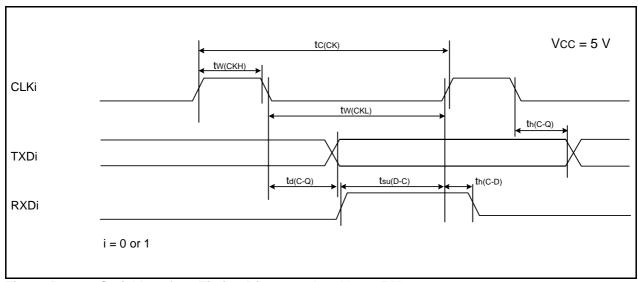
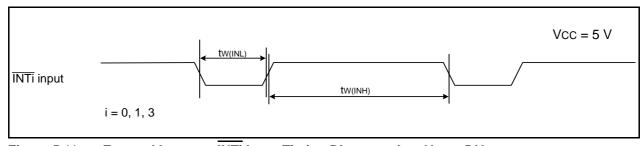


Figure 5.10 Serial Interface Timing Diagram when Vcc = 5 V

External Interrupt INTi (i = 0, 1, 3) Input **Table 5.21**

Symbol	Parameter		Standard		
Syllibol	Faianielei	Min. Max.	Unit		
tW(INH)	ĪNTi input "H" width	250 ⁽¹⁾	-	ns	
tW(INL)	INTi input "L" width	250 ⁽²⁾	-	ns	

- 1. When selecting the digital filter by the INTi input filter select bit, use an INTi input HIGH width of either (1/digital filter clock frequency × 3) or the minimum value of standard, whichever is greater.
- 2. When selecting the digital filter by the INTi input filter select bit, use an INTi input LOW width of either (1/digital filter clock frequency × 3) or the minimum value of standard, whichever is greater.



External Interrupt INTi Input Timing Diagram when Vcc = 5 V Figure 5.11

Table 5.22 Electrical Characteristics (3) [Vcc = 3 V]

Symbol	Parameter		Conc	Condition		Standard		
Syllibol	Fala	imeter	Conc	altion	Min.	Тур.	Max.	Unit
Vон	Output "H" voltage	Except P1_0 to P1_7, XOUT	Iон = -1 mA		Vcc - 0.5	_	Vcc	V
		P1_0 to P1_7	Drive capacity HIGH	Iон = -5 mA	Vcc - 0.5	=	Vcc	V
			Drive capacity LOW	Iон = -1 mA	Vcc - 0.5	-	Vcc	V
		XOUT	Drive capacity HIGH	Iон = -0.1 mA	Vcc - 0.5	ı	Vcc	V
			Drive capacity LOW	Іон = -50 μΑ	Vcc - 0.5	-	Vcc	V
Vol	Output "L" voltage	Except P1_0 to P1_7, XOUT	IoL = 1 mA		-	-	0.5	V
		P1_0 to P1_7	Drive capacity HIGH	IoL = 5 mA	-	ı	0.5	V
			Drive capacity LOW	IOL = 1 mA	-	-	0.5	V
		XOUT	Drive capacity HIGH	IOL = 0.1 mA	-	-	0.5	V
			Drive capacity LOW	IOL = 50 μA	-	_	0.5	V
VT+-VT-	Hysteresis	NT0, INT1, INT3, KI0, KI1, KI2, KI3, TRAIO, RXD0, RXD1, CLK0, CLK1, SSI, SCL, SDA, SSO			0.1	0.3	=	V
		RESET			0.1	0.4	-	V
Іін	Input "H" current	1	VI = 3 V, Vcc = 3 V		_	_	4.0	μΑ
lıL	Input "L" current		VI = 0 V, Vcc = 3	3 V	_	_	-4.0	μΑ
RPULLUP	Pull-up resistance		VI = 0 V, $Vcc = 3$	3 V	66	160	500	kΩ
RfXIN	Feedback resistance	XIN			_	3.0	_	МΩ
RfXCIN	Feedback resistance	XCIN			_	18	-	MΩ
VRAM	RAM hold voltage		During stop mode	e	1.8	-	_	V

^{1.} Vcc = 2.7 to 3.3 V at Topr = -20 to 85°C (N version) / -40 to 85°C (D version), f(XIN) = 10 MHz, unless otherwise specified.

Table 5.23 Electrical Characteristics (4) [Vcc = 3 V] (Topr = -20 to 85°C (N version) / -40 to 85°C (D version), unless otherwise specified.)

Symbol	Darameter		Condition		Standard		Lloit
Symbol	Parameter		Condition	Min.	Тур.	Max.	Unit
Icc	Power supply current (Vcc = 2.7 to 3.3 V) Single-chip mode,	Parameter Condition Min. Typ Min. Cock off High-speed on-chip oscillator on = 125 kHz Min. Cock off High-speed on-chip oscillator off Low-speed on-chip o	6	_	mA		
	other pins are Vss		High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz	I	2	Π	mA
		on-chip oscillator	High-speed on-chip oscillator on fOCO = 10 MHz Low-speed on-chip oscillator on = 125 kHz	Stand Min. Ty - 6 - 2 - 13 - 13 - 23 - 23 - 23 - 23	5	9	mA
		mode	High-speed on-chip oscillator on fOCO = 10 MHz Low-speed on-chip oscillator on = 125 kHz	-	2	-	mA
		on-chip oscillator off Low-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8, FMR47 = 1 XIN clock off	-	130	300	μА	
		'	High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz	-	130	300	μА
			High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz Program operation on RAM	_	30	_	μА
		Wait mode	High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz While a WAIT instruction is executed Peripheral clock operation VCA27 = VCA26 = VCA25 = 0	I	25	70	μА
			High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz While a WAIT instruction is executed Peripheral clock off VCA27 = VCA26 = VCA25 = 0	I	23	55	μА
			High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz (high drive) While a WAIT instruction is executed VCA27 = VCA26 = VCA25 = 0	I	3.8		μА
			High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz (low drive) While a WAIT instruction is executed	-	2.0	-	μА
		Stop mode	XIN clock off, Topr = 25°C High-speed on-chip oscillator off Low-speed on-chip oscillator off CM10 = 1 Peripheral clock off VCA27 = VCA26 = VCA25 = 0	_	0.7	3.0	μА
			XIN clock off, Topr = 85°C High-speed on-chip oscillator off Low-speed on-chip oscillator off CM10 = 1 Peripheral clock off VCA27 = VCA26 = VCA25 = 0	-	1.1	_	μА

Timing requirements

(Unless Otherwise Specified: Vcc = 3 V, Vss = 0 V at Topr = 25°C) [Vcc = 3 V]

Table 5.24 XIN Input, XCIN Input

Symbol	Parameter	Stan	Unit	
	i alametei		Max.	Offic
tc(XIN)	XIN input cycle time	100	-	ns
twh(xin)	XIN input "H" width	40	-	ns
tWL(XIN)	XIN input "L" width	40	-	ns
tc(XCIN)	XCIN input cycle time	14	=	μS
twh(xcin)	XCIN input "H" width	7	-	μS
tWL(XCIN)	XCIN input "L" width	7	=	μS

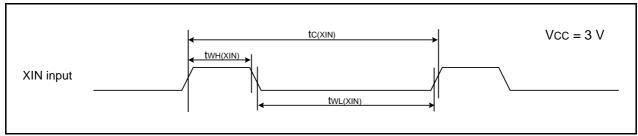


Figure 5.12 XIN Input and XCIN Input Timing Diagram when Vcc = 3 V

Table 5.25 TRAIO Input

Symbol	Parameter		Standard		
Symbol	raidilletei	Min.	Max.	Unit	
tc(TRAIO)	TRAIO input cycle time	300	=	ns	
twh(traio)	TRAIO input "H" width	120	=	ns	
twl(traio)	TRAIO input "L" width	120	=	ns	

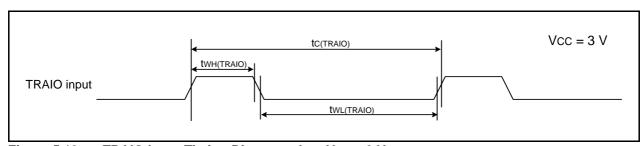


Figure 5.13 TRAIO Input Timing Diagram when Vcc = 3 V

Table 5.26 Serial Interface

Symbol	Symbol Parameter		Standard		
Symbol			Max.	Unit	
tc(CK)	CLKi input cycle time	300	=	ns	
tW(CKH)	CLKi input "H" width	150	-	ns	
tW(CKL)	CLKi Input "L" width	150	-	ns	
td(C-Q)	TXDi output delay time	-	80	ns	
th(C-Q)	TXDi hold time	0	-	ns	
tsu(D-C)	RXDi input setup time	70	=	ns	
th(C-D)	RXDi input hold time	90	-	ns	

i = 0 or 1

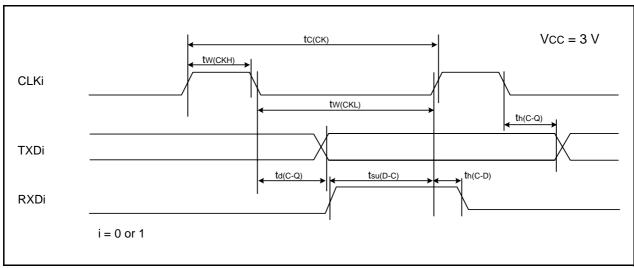


Figure 5.14 Serial Interface Timing Diagram when Vcc = 3 V

Table 5.27 External Interrupt \overline{INTi} (i = 0, 1, 3) Input

Symbol	Symbol Parameter -		Standard	
Symbol	Faianielei	Min.	Max.	Unit
tW(INH)	INTi input "H" width	380(1)	_	ns
tW(INL)	INTi input "L" width	380(2)		ns

- 1. When selecting the digital filter by the INTi input filter select bit, use an INTi input HIGH width of either (1/digital filter clock frequency × 3) or the minimum value of standard, whichever is greater.
- 2. When selecting the digital filter by the $\overline{\text{INTi}}$ input filter select bit, use an $\overline{\text{INTi}}$ input LOW width of either (1/digital filter clock frequency × 3) or the minimum value of standard, whichever is greater.

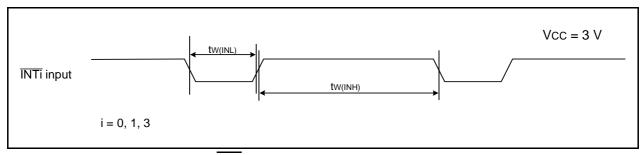


Figure 5.15 External Interrupt INTi Input Timing Diagram when Vcc = 3 V

Table 5.28 Electrical Characteristics (5) [VCC = 2.2 V]

Cumbal	Doro	um atar	er Condition		Standard			Unit
Symbol	Para	ımeter	Cond	aition	Min.	Тур.	Max.	Unit
Vон	Output "H" voltage	Except P1_0 to P1_7, XOUT	Iон = -1 mA		Vcc - 0.5	=	Vcc	V
		P1_0 to P1_7	Drive capacity HIGH	Iон = -2 mA	Vcc - 0.5	-	Vcc	V
			Drive capacity LOW	Iон = -1 mA	Vcc - 0.5	_	Vcc	V
		XOUT	Drive capacity HIGH	Iон = -0.1 mA	Vcc - 0.5	=	Vcc	V
			Drive capacity LOW	Ιοн = -50 μΑ	Vcc - 0.5	=	Vcc	V
Vol	Output "L" voltage	Except P1_0 to P1_7, XOUT	IoL = 1 mA		=	=	0.5	V
		P1_0 to P1_7	Drive capacity HIGH	IoL = 2 mA	-	-	0.5	V
			Drive capacity LOW	IoL = 1 mA	=	=	0.5	V
		XOUT	Drive capacity HIGH	IOL = 0.1 mA	=	=	0.5	V
			Drive capacity LOW	IOL = 50 μA	=	-	0.5	V
VT+-VT-	Hysteresis	INTO, INT1, INT3, KIO, KI1, KI2, KI3, TRAIO, RXDO, RXD1, CLK0, CLK1, SSI, SCL, SDA, SSO			0.05	0.3	_	V
		RESET			0.05	0.15	-	V
lін	Input "H" current	I.	VI = 2.2 V		=	_	4.0	μА
lıL	Input "L" current		VI = 0 V		-	_	-4.0	μА
RPULLUP	Pull-up resistance		VI = 0 V		100	200	600	kΩ
RfXIN	Feedback resistance	XIN			=	5	=	MΩ
RfXCIN	Feedback resistance	XCIN			-	35	_	ΜΩ
VRAM	RAM hold voltage		During stop mod	e	1.8	-		V

^{1.} Vcc = 2.2 V at $T_{opr} = -20$ to $85^{\circ}C$ (N version) / -40 to $85^{\circ}C$ (D version), f(XIN) = 5 MHz, unless otherwise specified.

Table 5.29 Electrical Characteristics (6) [Vcc = 2.2 V] (Topr = -20 to 85°C (N version) / -40 to 85°C (D version), unless otherwise specified.)

Symbol	Parameter	Condition		Standard			Unit
- y,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,	i didilictei			Min.	Тур.	Max.	Jiil
lcc	Power supply current (Vcc = 2.2 to 2.7 V) Single-chip mode, output pins are open,	High-speed clock mode	XIN = 5 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz No division	-	3.5		mA
output pins are open, other pins are Vss		XIN = 5 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8	_	1.5	_	mA	
	High-speed on-chip oscillator mode	XIN clock off High-speed on-chip oscillator on fOCO = 5 MHz Low-speed on-chip oscillator on = 125 kHz No division	_	3.5		mA	
		mode	XIN clock off High-speed on-chip oscillator on fOCO = 5 MHz Low-speed on-chip oscillator on = 125 kHz Divide-by-8	_	1.5		mA
		Low-speed on-chip oscillator mode	XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8, FMR47 = 1	_	100	230	μА
		Low-speed clock mode	XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz FMR47 = 1	-	100	230	μА
	Wait		XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz Program operation on RAM Flash memory off, FMSTP = 1	-	25		μА
		Wait mode	XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz While a WAIT instruction is executed Peripheral clock operation VCA27 = VCA26 = VCA25 = 0 VCA20 = 1	_	22	60	μА
			XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz While a WAIT instruction is executed Peripheral clock off VCA27 = VCA26 = VCA25 = 0 VCA20 = 1	-	20	55	μА
			XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz (high drive) While a WAIT instruction is executed VCA27 = VCA26 = VCA25 = 0 VCA20 = 1	-	3.0	-	μА
			XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz (low drive) While a WAIT instruction is executed VCA27 = VCA26 = VCA25 = 0 VCA20 = 1	-	1.8	-	μА
		Stop mode	XIN clock off, Topr = 25°C High-speed on-chip oscillator off Low-speed on-chip oscillator off CM10 = 1 Peripheral clock off VCA27 = VCA26 = VCA25 = 0	=	0.7	3.0	μА
			XIN clock off, Topr = 85°C High-speed on-chip oscillator off Low-speed on-chip oscillator off CM10 = 1 Peripheral clock off VCA27 = VCA26 = VCA25 = 0	_	1.1	_	μА

Timing requirements

(Unless Otherwise Specified: Vcc = 2.2 V, Vss = 0 V at Topr = 25°C) [Vcc = 2.2 V]

Table 5.30 XIN Input, XCIN Input

Symbol	Parameter		Standard		
Symbol	Farameter	Min.	Max.	Unit	
tc(XIN)	XIN input cycle time	200	-	ns	
twh(xin)	XIN input "H" width	90	-	ns	
twl(xin)	XIN input "L" width	90	-	ns	
tc(XCIN)	XCIN input cycle time	14	-	μS	
twh(xcin)	XCIN input "H" width	7	=	μS	
tWL(XCIN)	XCIN input "L" width	7	_	μS	

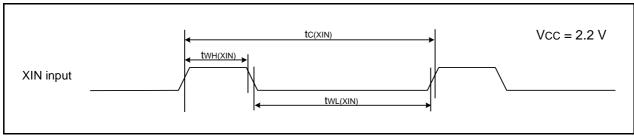


Figure 5.16 XIN Input and XCIN Input Timing Diagram when Vcc = 2.2 V

Table 5.31 TRAIO Input

Symbol	Parameter		Standard		
Symbol			Max.	Unit	
tc(TRAIO)	TRAIO input cycle time	500	=	ns	
twh(traio)	TRAIO input "H" width	200	=	ns	
twl(traio)	TRAIO input "L" width	200	=	ns	

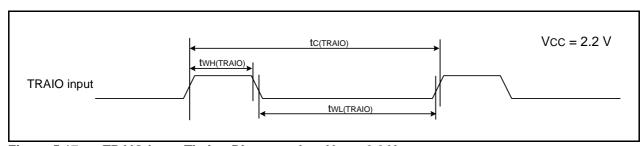


Figure 5.17 TRAIO Input Timing Diagram when Vcc = 2.2 V

Table 5.32 Serial Interface	Table	5.32	Serial In	terface
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Symbol	Symbol Parameter		Standard		
Symbol			Max.	Unit	
tc(CK)	CLKi input cycle time	800	-	ns	
tW(CKH)	CLKi input "H" width	400	-	ns	
tW(CKL)	CLKi input "L" width	400	-	ns	
td(C-Q)	TXDi output delay time	=	200	ns	
th(C-Q)	TXDi hold time	0	-	ns	
tsu(D-C)	RXDi input setup time	150	=	ns	
th(C-D)	RXDi input hold time	90	-	ns	

i = 0 or 1

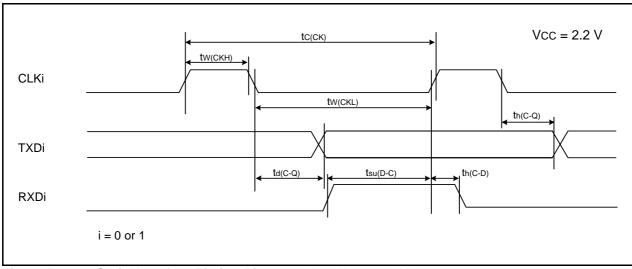


Figure 5.18 Serial Interface Timing Diagram when Vcc = 2.2 V

Table 5.33 External Interrupt \overline{INTi} (i = 0, 1, 3) Input

Symbol	Parameter	Standard		Unit
Symbol	i didilicici		Max.	Offic
tw(INH)	INTi input "H" width	1000(1)	-	ns
tw(INL)	INTi input "L" width	1000 ⁽²⁾	П	ns

- 1. When selecting the digital filter by the INTi input filter select bit, use an INTi input HIGH width of either (1/digital filter clock frequency × 3) or the minimum value of standard, whichever is greater.
- 2. When selecting the digital filter by the INTi input filter select bit, use an INTi input LOW width of either (1/digital filter clock frequency × 3) or the minimum value of standard, whichever is greater.

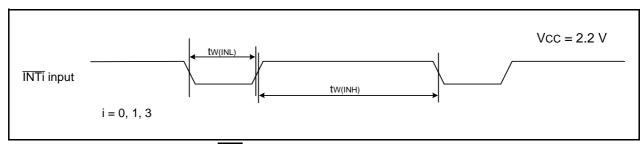


Figure 5.19 External Interrupt INTi Input Timing Diagram when Vcc = 2.2 V

J, K Version 5.2

Table 5.34 Absolute Maximum Ratings

Symbol	Parameter	Condition	Rated Value	Unit
Vcc/AVcc	Supply voltage		-0.3 to 6.5	V
Vı	Input voltage		-0.3 to Vcc + 0.3	V
Vo	Output voltage		-0.3 to Vcc + 0.3	V
Pd	Power dissipation	-40 °C ≤ Topr ≤ 85 °C	300	mW
		85 °C ≤ Topr ≤ 125 °C	125	mW
Topr	Operating ambient temperature		-40 to 85 (J version) / -40 to 125 (K version)	°C
Tstg	Storage temperature		-65 to 150	°C

Table 5.35 Recommended Operating Conditions

Symbol	Dor	Parameter Conditions		Unit			
Symbol	Fale	ametei	Conditions	Min.	Тур.	Max.	Offic
Vcc/AVcc	Supply voltage			2.7	_	5.5	V
Vss/AVss	Supply voltage			-	0	_	V
ViH	Input "H" voltage			0.8 Vcc	_	Vcc	V
VIL	Input "L" voltage			0	_	0.2 Vcc	V
IOH(sum)	Peak sum output "H" current	Sum of all pins IOH(peak)		_	-	-60	mA
IOH(peak)	Peak output "H" current			-	=	-10	mA
IOH(avg)	Average output "H" current			-	=	-5	mA
IOL(sum)	Peak sum output "L" currents	Sum of all pins IOL(peak)		_	-	60	mA
IOL(peak)	Peak output "L" currents			_	-	10	mA
IOL(avg)	Average output "L" current			_	-	5	mA
f(XIN)	XIN) XIN clock input oscillation frequency		3.0 V ≤ Vcc ≤ 5.5 V (other than K version)	0	=	20	MHz
			3.0 V ≤ Vcc ≤ 5.5 V (K version)	0	_	16	MHz
			2.7 V ≤ Vcc < 3.0 V	0	_	10	MHz
=	System clock	OCD2 = 0 XIN clock selected	3.0 V ≤ Vcc ≤ 5.5 V (other than K version)	0	=	20	MHz
			3.0 V ≤ Vcc ≤ 5.5 V (K version)	0	_	16	MHz
			2.7 V ≤ Vcc < 3.0 V	0	_	10	MHz
		OCD2 = 1 On-chip oscillator clock selected	FRA01 = 0 Low-speed on-chip oscillator clock selected	-	125	=	kHz
			FRA01 = 1 High-speed on-chip oscillator clock selected (other than K version)		-	20	MHz
			FRA01 = 1 High-speed on-chip oscillator clock selected	-	_	10	MHz

- 1. Vcc = 2.7 to 5.5 V at $T_{opr} = -40$ to $85^{\circ}C$ (J version) / -40 to $125^{\circ}C$ (K version), unless otherwise specified.
- 2. The average output current indicates the average value of current measured during 100 ms.

Table 5.36 A/D Converter Cha	aracteristics
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Cymphol		Parameter	Conditions	Standard			Unit
Symbol	'	Parameter	Arameter Conditions		Тур.	Max.	Offic
_	Resolution		Vref = AVCC	-	-	10	Bits
_	Absolute	10-bit mode	φAD = 10 MHz, Vref = AVCC = 5.0 V	-	-	±3	LSB
	accuracy	8-bit mode	φAD = 10 MHz, Vref = AVCC = 5.0 V	-	-	±2	LSB
		10-bit mode	φAD = 10 MHz, Vref = AVCC = 3.3 V	-	-	±5	LSB
		8-bit mode	φAD = 10 MHz, Vref = AVCC = 3.3 V	_	_	±2	LSB
Rladder	Resistor ladder		Vref = AVCC	10	_	40	kΩ
tconv	Conversion time	10-bit mode	φAD = 10 MHz, Vref = AVCC = 5.0 V	3.3	_	_	μS
		8-bit mode	φAD = 10 MHz, Vref = AVCC = 5.0 V	2.8	_	_	μS
Vref	Reference voltag	e		2.7	-	AVcc	V
VIA	Analog input volta	age ⁽²⁾		0	-	AVcc	V
_	A/D operating	Without sample and hold		0.25	-	10	MHz
	clock frequency	With sample and hold		1	_	10	MHz

- 1. AVcc = 2.7 to 5.5 V at $T_{opr} = -40$ to $85^{\circ}C$ (J version) / -40 to $125^{\circ}C$ (K version), unless otherwise specified.
- 2. When the analog input voltage is over the reference voltage, the A/D conversion result will be 3FFh in 10-bit mode and FFh in 8-bit mode.

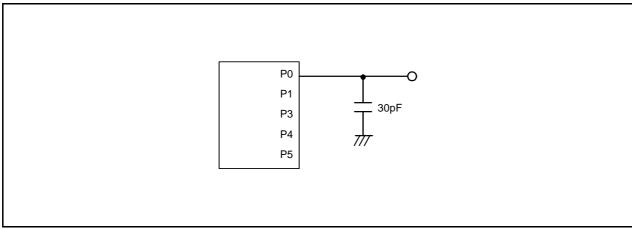


Figure 5.20 Ports P0, P1, and P3 to P5 Timing Measurement Circuit

Table 5.37 Flash Memory (Program ROM) Electrical Characteristics

Symbol	Parameter	Conditions		ard	Unit	
Symbol	Farameter	Coriditions	Min.	Тур.	Max.	Offic
=	Program/erase endurance ⁽²⁾	R8C/26 Group	100 ⁽³⁾	=	=	times
		R8C/27 Group	1,000(3)	-	-	times
_	Byte program time		-	50	400	μS
_	Block erase time		-	0.4	9	S
td(SR-SUS)	Time delay from suspend request until		=	-	97 + CPU clock	μS
	suspend				× 6 cycles	
_	Interval from erase start/restart until		650	_	-	μS
	following suspend request					
_	Interval from program start/restart until		0	_	_	ns
	following suspend request					
_	Time from suspend until program/erase		-	=	3 + CPU clock	μS
	restart				× 4 cycles	
=	Program, erase voltage		2.7	-	5.5	V
=	Read voltage		2.7	-	5.5	V
=	Program, erase temperature		0	=	60	°C
_	Data hold time ⁽⁷⁾	Ambient temperature = 55°C	20	_	_	year

- NOTES:

 1. Vcc = 2.7 to 5.5 V at Topr = 0 to 60°C, unless otherwise specified.
 - 2. Definition of programming/erasure endurance

The programming and erasure endurance is defined on a per-block basis.

If the programming and erasure endurance is n (n = 100 or 1,000), each block can be erased n times. For example, if 1,024 1-byte writes are performed to different addresses in block A, a 1 Kbyte block, and then the block is erased, the programming/erasure endurance still stands at one.

However, the same address must not be programmed more than once per erase operation (overwriting prohibited).

- 3. Endurance to guarantee all electrical characteristics after program and erase. (1 to Min. value can be guaranteed).
- 4. In a system that executes multiple programming operations, the actual erasure count can be reduced by writing to sequential addresses in turn so that as much of the block as possible is used up before performing an erase operation. For example, when programming groups of 16 bytes, the effective number of rewrites can be minimized by programming up to 128 groups before erasing them all in one operation. It is also advisable to retain data on the erasure endurance of each block and limit the number of erase operations to a certain number.
- 5. If an error occurs during block erase, attempt to execute the clear status register command, then execute the block erase command at least three times until the erase error does not occur.
- 6. Customers desiring program/erase failure rate information should contact their Renesas technical support representative.
- 7. The data hold time includes time that the power supply is off or the clock is not supplied.

Table 5.38 Flash Memory (Data flash Block A, Block B) Electrical Characteristics⁽⁴⁾

Symbol	Parameter	Conditions		Standard			
Symbol	Farameter	Conditions	Min.	Тур.	Max.	Unit	
_	Program/erase endurance ⁽²⁾		10,000(3)	-	_	times	
_	Byte program time (program/erase endurance ≤ 1,000 times)		_	50	400	μS	
_	Byte program time (program/erase endurance > 1,000 times)		_	65	_	μS	
-	Block erase time (program/erase endurance ≤ 1,000 times)		_	0.2	9	S	
_	Block erase time (program/erase endurance > 1,000 times)		_	0.3	_	S	
td(SR-SUS)	Time delay from suspend request until suspend		_	-	97 + CPU clock × 6 cycles	μS	
_	Interval from erase start/restart until following suspend request		650	=	_	μS	
_	Interval from program start/restart until following suspend request		0	-	_	ns	
_	Time from suspend until program/erase restart		_	-	3 + CPU clock × 4 cycles	μS	
=	Program, erase voltage		2.7	-	5.5	V	
=	Read voltage		2.7	П	5.5	V	
_	Program, erase temperature		-40	-	85(8)	°C	
_	Data hold time ⁽⁹⁾	Ambient temperature = 55°C	20	ı	=	year	

- 1. Vcc = 2.7 to 5.5 V at Topr = -40 to 85°C (J version) / -40 to 125°C (K version), unless otherwise specified.
- 2. Definition of programming/erasure endurance
 - The programming and erasure endurance is defined on a per-block basis.
 - If the programming and erasure endurance is n (n = 10,000), each block can be erased n times. For example, if 1,024 1-byte writes are performed to different addresses in block A, a 1 Kbyte block, and then the block is erased, the programming/erasure endurance still stands at one.
 - However, the same address must not be programmed more than once per erase operation (overwriting prohibited).
- 3. Endurance to guarantee all electrical characteristics after program and erase. (1 to Min. value can be guaranteed).
- 4. Standard of block A and block B when program and erase endurance exceeds 1,000 times. Byte program time to 1,000 times is the same as that in program ROM.
- 5. In a system that executes multiple programming operations, the actual erasure count can be reduced by writing to sequential addresses in turn so that as much of the block as possible is used up before performing an erase operation. For example, when programming groups of 16 bytes, the effective number of rewrites can be minimized by programming up to 128 groups before erasing them all in one operation. In addition, averaging the erasure endurance between blocks A and B can further reduce the actual erasure endurance. It is also advisable to retain data on the erasure endurance of each block and limit the number of erase operations to a certain number.
- 6. If an error occurs during block erase, attempt to execute the clear status register command, then execute the block erase command at least three times until the erase error does not occur.
- 7. Customers desiring program/erase failure rate information should contact their Renesas technical support representative.
- 8. 125°C for K version.
- 9. The data hold time includes time that the power supply is off or the clock is not supplied.

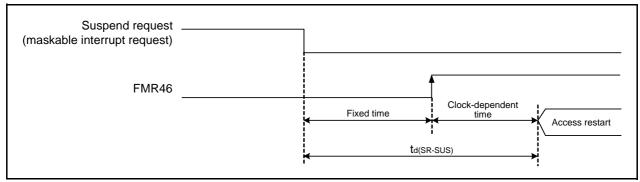


Figure 5.21 Time delay until Suspend

Table 5.39 Voltage Detection 1 Circuit Electrical Characteristics

Symbol	Parameter	Condition	Standard			Unit
Syllibol	Tribot Farameter Condition		Min.	Тур.	Max.	Offic
Vdet1	Voltage detection level ^(2, 4)		2.70	2.85	3.0	V
td(Vdet1-A)	Voltage monitor 1 reset generation time ⁽⁵⁾		_	40	200	μS
_	Voltage detection circuit self power consumption	VCA26 = 1, Vcc = 5.0 V	_	0.6	_	μΑ
td(E-A)	Waiting time until voltage detection circuit operation starts ⁽³⁾		=	-	100	μS
Vccmin	MCU operating voltage minimum value		2.70	-	_	V

- 1. The measurement condition is Vcc = 2.7 to 5.5 V and Topr = -40 to 85°C (J version) / -40 to 125°C (K version).
- 2. Hold Vdet2 > Vdet1.
- 3. Necessary time until the voltage detection circuit operates when setting to 1 again after setting the VCA26 bit in the VCA2 register to 0.
- 4. This parameter shows the voltage detection level when the power supply drops. The voltage detection level when the power supply rises is higher than the voltage detection level when the power supply drops by approximately 0.1 V.
- 5. Time until the voltage monitor 1 reset is generated after the voltage passes V_{det1} when V_{CC} falls. When using the digital filter, its sampling time is added to t_d(V_{det1}-A). When using the voltage monitor 1 reset, maintain this time until V_{CC} = 2.0 V after the voltage passes V_{det1} when the power supply falls.

Table 5.40 Voltage Detection 2 Circuit Electrical Characteristics

Symbol	Parameter	Condition		Unit		
Symbol	Symbol		Min.	Тур.	Max.	Offic
Vdet2	Voltage detection level ⁽²⁾		3.3	3.6	3.9	V
td(Vdet2-A)	Voltage monitor 2 reset/interrupt request generation time ^(3, 5)		=	40	200	μS
=	Voltage detection circuit self power consumption	VCA27 = 1, Vcc = 5.0 V	=	0.6	_	μΑ
td(E-A)	Waiting time until voltage detection circuit operation starts ⁽⁴⁾			=	100	μS

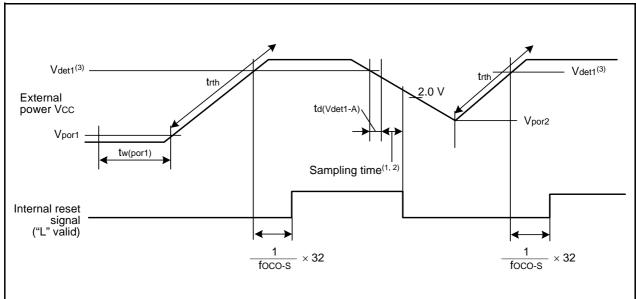
- 1. The measurement condition is Vcc = 2.7 to 5.5 V and Topr = -40 to 85°C (J version) / -40 to 125°C (K version).
- 2. Hold Vdet2 > Vdet1
- 3. Time until the voltage monitor 2 reset/interrupt request is generated after the voltage passes Vdet2.
- 4. Necessary time until the voltage detection circuit operates after setting to 1 again after setting the VCA27 bit in the VCA2 register to 0.
- 5. When using the digital filter, its sampling time is added to td(Vdet2-A). When using the voltage monitor 2 reset, maintain this time until Vcc = 2.0 V after the voltage passes Vdet2 when the power supply falls.



Table 5.41 Power-on Reset Circuit, Voltage Monitor 1 Reset Electrical Characteristics	Table 5.41	Power-on Reset Circuit,	Voltage Monitor 1 Reset	t Electrical Characteristics(3)
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Symbol	Parameter	Condition		Unit		
Symbol	Faranielei	Condition	Min.	Тур.	Max.	Offic
Vpor1	Power-on reset valid voltage ⁽⁴⁾		_	-	0.1	V
Vpor2	Power-on reset or voltage monitor 1 reset valid voltage		0	_	Vdet1	V
trth	External power Vcc rise gradient	Vcc ≤ 3.6 V	20(2)	-	_	mV/msec
		Vcc > 3.6 V	20(2)	=	2,000	mV/msec

- 1. The measurement condition is Topr = -40 to 85°C (J version) / -40 to 125°C (K version), unless otherwise specified.
- 2. This condition (the minimum value of external power Vcc rise gradient) does not apply if $V_{por2} \ge 1.0 \text{ V}$.
- 3. To use the power-on reset function, enable voltage monitor 1 reset by setting the LVD1ON bit in the OFS register to 0, the VW1C0 and VW1C6 bits in the VW1C register to 1 respectively, and the VCA26 bit in the VCA2 register to 1.
- 4. tw(por1) indicates the duration the external power Vcc must be held below the effective voltage (Vpor1) to enable a power on reset. When turning on the power for the first time, maintain tw(por1) for 30 s or more if -20°C ≤ Topr ≤ 125°C, maintain tw(por1) for 3,000 s or more if -40°C ≤ Topr < -20°C.</p>



- 1. When using the voltage monitor 1 digital filter, ensure VCC is $2.0\ V$ or higher during the sampling time.
- 2. The sampling clock can be selected. Refer to 6. Voltage Detection Circuit of Hardware Manual for details.
- 3. Vdet1 indicates the voltage detection level of the voltage detection 1 circuit. Refer to 6. Voltage Detection Circuit of Hardware Manual for details.

Figure 5.22 Reset Circuit Electrical Characteristics

Table 5.42 High-speed On-Chip Oscillator Circuit Electrical Characteristics

Symbol	Parameter	Condition		Standard		Unit
Symbol	Farameter	Condition	Min.	Тур.	Max.	Offic
fOCO40M	High-speed on-chip oscillator frequency temperature · supply voltage dependence	Vcc = 4.75 to 5.25 V $0^{\circ}C \leq Topr \leq 60^{\circ}C^{(2)}$	39.2	40	40.8	MHz
		Vcc = 3.0 to 5.5 V -20°C \leq Topr \leq 85°C ⁽²⁾	38.8	40	41.2	MHz
		Vcc = 3.0 to 5.5 V -40°C \leq Topr \leq 85°C ⁽²⁾	38.4	40	41.6	MHz
		Vcc = 3.0 to 5.5 V -40°C \leq Topr \leq 125°C ⁽²⁾	38	40	42	MHz
		Vcc = 2.7 to 5.5 V -40°C \leq Topr \leq 125°C(2)	37.6	40	42.4	MHz
_	Value in FRA1 register after reset		08h	-	F7h	_
=	Oscillation frequency adjustment unit of high- speed on-chip oscillator	Adjust FRA1 register (value after reset) to -1	-	+0.3	=	MHz
_	Oscillation stability time		-	10	100	μS
_	Self power consumption at oscillation	Vcc = 5.0 V, Topr = 25°C	-	400	-	μА

- 1. Vcc = 2.7 to 5.5 V, Topr = -40 to $85^{\circ}C$ (J version) / -40 to $125^{\circ}C$ (K version), unless otherwise specified.
- 2. These standard values show when the FRA1 register value after reset is assumed.

Table 5.43 Low-speed On-Chip Oscillator Circuit Electrical Characteristics

Symbol	Parameter	Condition		Unit		
Symbol		Condition	Min.	Тур.	Max.	Offic
fOCO-S	Low-speed on-chip oscillator frequency		40 125 250		kHz	
_	Oscillation stability time		-	10	100	μS
_	Self power consumption at oscillation	$VCC = 5.0 \text{ V}, \text{ Topr} = 25^{\circ}\text{C}$	_	15	_	μА

NOTE:

Table 5.44 Power Supply Circuit Timing Characteristics

Svmbol	Parameter	Condition	Standard			Unit
Symbol	Symbol Farameter Condition		Min.	Тур.	Max.	Offic
td(P-R)	Time for internal power supply stabilization during power-on ⁽²⁾		1	=	2000	μS
td(R-S)	STOP exit time ⁽³⁾		-	-	150	μS

- 1. The measurement condition is Vcc = 2.7 to 5.5 V and T_{opr} = 25°C.
- 2. Waiting time until the internal power supply generation circuit stabilizes during power-on.
- 3. Time until system clock supply starts after the interrupt is acknowledged to exit stop mode.

^{1.} Vcc = 2.7 to 5.5 V, Topr = -40 to 85°C (J version) / -40 to 125°C (K version), unless otherwise specified.

Table 5.45 Timing Requirements of Clock Synchronous Serial I/O with Chip Select(1)

Cumbal	Paramete	_	Conditions		Stand	lard	Unit
Symbol	Paramete	er .	Conditions	Min.	Тур.	Max.	
tsucyc	SSCK clock cycle time	е		4	-	=	tcyc(2)
tHI	SSCK clock "H" width			0.4	-	0.6	tsucyc
tLO	SSCK clock "L" width			0.4	_	0.6	tsucyc
trise SSCK clock risin time	SSCK clock rising	Master		=	=	1	tcyc(2)
		time	Slave		=	_	1
tfall	SSCK clock falling	Master		-	-	1	tcyc(2)
	time	Slave		=	_	1	μS
tsu	SSO, SSI data input s	setup time		100	-	-	ns
tH	SSO, SSI data input h	nold time		1	=	=	tcyc(2)
tLEAD	SCS setup time	Slave		1tcyc + 50	-	-	ns
tLAG	SCS hold time	Slave		1tcyc + 50	=	=	ns
top	SSO, SSI data output	delay time		_	-	1	tcyc(2)
tsa	SSI slave access time	9		-	_	1.5tcyc + 100	ns
tor	SSI slave out open tir	ne		_	_	1.5tcyc + 100	ns

- 1. Vcc = 2.7 to 5.5 V, Vss = 0 V at $T_{opr} = -40$ to $85^{\circ}C$ (J version) / -40 to $125^{\circ}C$ (K version), unless otherwise specified. 2. 1tCyc = 1/f1(s)

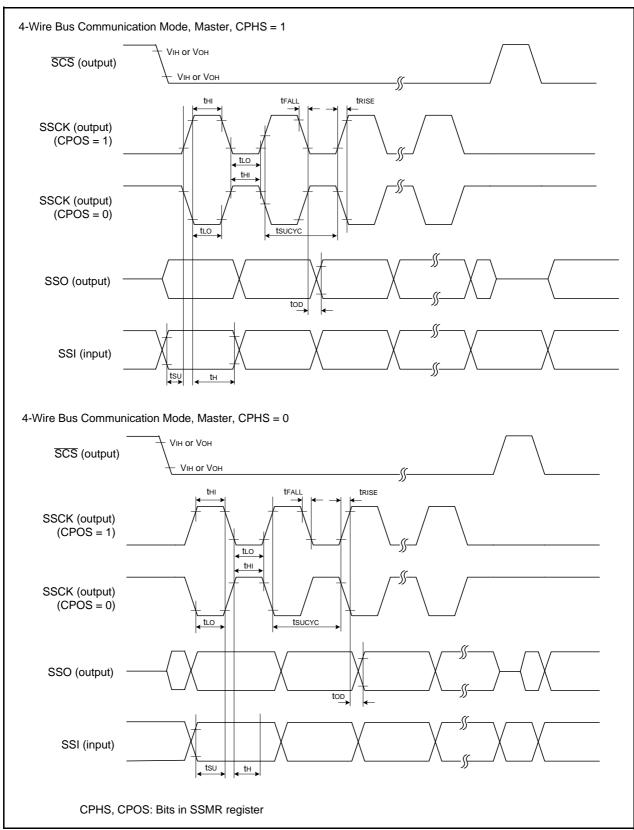


Figure 5.23 I/O Timing of Clock Synchronous Serial I/O with Chip Select (Master)

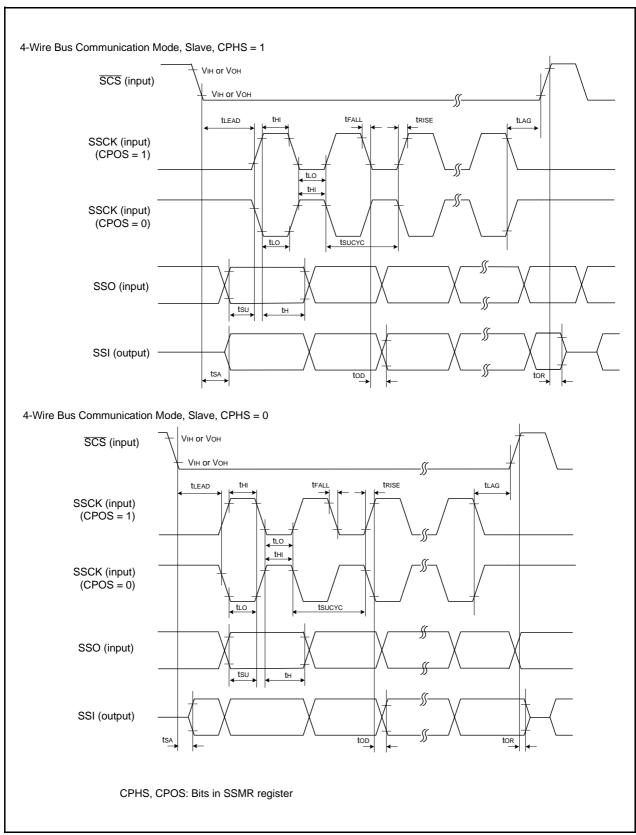


Figure 5.24 I/O Timing of Clock Synchronous Serial I/O with Chip Select (Slave)

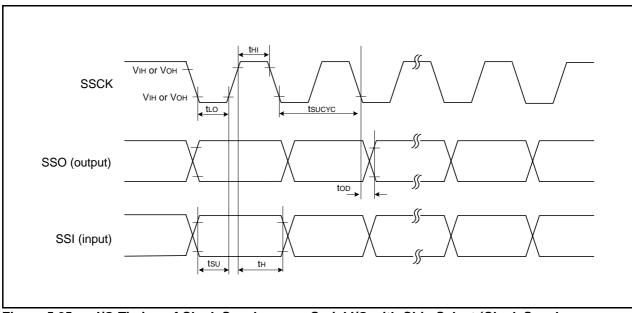


Figure 5.25 I/O Timing of Clock Synchronous Serial I/O with Chip Select (Clock Synchronous Communication Mode)

Table 5.46 Timing Requirements of I²C bus Interface⁽¹⁾

Symbol	Parameter	Condition	St	Unit		
Syllibol	Farameter	Condition	Min.	Тур.	Max.	
tscl	SCL input cycle time		12tcyc + 600 ⁽²⁾	-	_	ns
tsclh	SCL input "H" width		3tcyc + 300 ⁽²⁾	=	-	ns
tscll	SCL input "L" width		5tcyc + 500 ⁽²⁾	=	-	ns
tsf	SCL, SDA input fall time		-	-	300	ns
tsp	SCL, SDA input spike pulse rejection time		-	-	1tcyc(2)	ns
tBUF	SDA input bus-free time		5tcyc(2)	-	-	ns
tstah	Start condition input hold time		3tcyc(2)	=	-	ns
tstas	Retransmit start condition input setup time		3tcyc(2)	=	-	ns
tstop	Stop condition input setup time		3tcyc(2)	-	-	ns
tsdas	Data input setup time		1tcyc + 20 ⁽²⁾	-	-	ns
tsdah	Data input hold time		0	-	-	ns

- 1. Vcc = 2.7 to 5.5 V, Vss = 0 V at Topr = -40 to $85^{\circ}C$ (J version) / -40 to $125^{\circ}C$ (K version), unless otherwise specified.
- 2. 1tcyc = 1/f1(s)

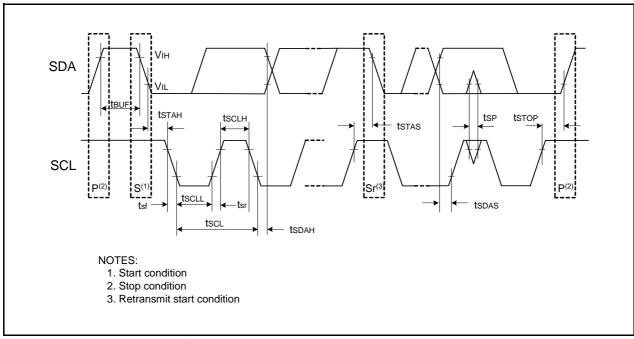


Figure 5.26 I/O Timing of I²C bus Interface

Table 5.47 Electrical Characteristics (1) [Vcc = 5 V]

Symbol	Por	Parameter		Condition		tandard		Unit
Symbol	Fai	ameter	Condition		Min.	Тур. Мах.		Offit
Vон	Output "H" voltage	Except XOUT	Iон = -5 mA		Vcc - 2.0	-	Vcc	V
			Іон = -200 μА		Vcc - 0.3	-	Vcc	V
		XOUT	Drive capacity HIGH	Iон = -1 mA	Vcc - 2.0	=	Vcc	V
			Drive capacity LOW	IOH = -500 μA	Vcc - 2.0	=	Vcc	V
Vol	Output "L" voltage	Except XOUT	IoL = 5 mA		=	-	2.0	V
			IOL = 200 μA		=	-	0.45	V
		XOUT	Drive capacity HIGH	IoL = 1 mA	=	-	2.0	V
			Drive capacity LOW	IoL = 500 μA	=	-	2.0	V
VT+-VT-	Hysteresis	INTO, INT1, INT3, KIO, KI1, KI2, KI3, TRAIO, RXD0, RXD1, CLK0, CLK1, SSI, SCL, SDA, SSO			0.1	0.5	-	>
		RESET			0.1	1.0	_	V
Іін	Input "H" current	•	VI = 5 V, Vcc = 5V		_	-	5.0	μА
lıL	Input "L" current		VI = 0 V, Vcc = 5V		_	_	-5.0	μΑ
RPULLUP	Pull-up resistance		VI = 0 V, Vcc = 5V		30	50	167	kΩ
RfXIN	Feedback resistance	XIN			-	1.0	_	ΜΩ
VRAM	RAM hold voltage		During stop mode		2.0	-	-	V

^{1.} Vcc = 4.2 to 5.5 V at Topr = -40 to 85°C (J version) / -40 to 125°C (K version), f(XIN) = 20 MHz, unless otherwise specified.

Table 5.48 Electrical Characteristics (2) [Vcc = 5 V] (Topr = -40 to 85°C (J version) / -40 to 125°C (K version), unless otherwise specified.)

Symbol	Parameter	Parameter Condition			Standar	d	ناما ا
Symbol	Parameter		Condition	Min.	Тур.	Max.	Unit
lcc	Power supply current (Vcc = 3.3 to 5.5 V) Single-chip mode,	High-speed clock mode	XIN = 20 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz No division	-	10	17	mA
output pins are open, other pins are Vss	output pins are open, other pins are Vss		XIN = 16 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz No division	_	9	15	mA
	XIN = 10 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz No division	_	6	-	mA		
			XIN = 20 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8	-	5	=	mA
			XIN = 16 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8	-	4	=	mA
			XIN = 10 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8	_	2.5	_	mA
		High-speed on-chip oscillator	XIN clock off High-speed on-chip oscillator on fOCO = 20 MHz (J version) Low-speed on-chip oscillator on = 125 kHz No division	-	10	15	mA
		mode	XIN clock off High-speed on-chip oscillator on fOCO = 20 MHz (J version) Low-speed on-chip oscillator on = 125 kHz Divide-by-8	-	4	-	mA
			XIN clock off High-speed on-chip oscillator on fOCO = 10 MHz Low-speed on-chip oscillator on = 125 kHz No division	-	5.5	10	m/
			XIN clock off High-speed on-chip oscillator on fOCO = 10 MHz Low-speed on-chip oscillator on = 125 kHz Divide-by-8	_	2.5	-	mA
		Low-speed on-chip oscillator mode	XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8, FMR47 = 1	-	130	300	μА
		Wait mode	XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz While a WAIT instruction is executed Peripheral clock operation VCA27 = VCA26 = VCA25 = 0 VCA20 = 1	_	25	75	μА
			XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz While a WAIT instruction is executed Peripheral clock off VCA27 = VCA26 = VCA25 = 0 VCA20 = 1	-	23	60	μА
		Stop mode	XIN clock off, Topr = 25°C High-speed on-chip oscillator off Low-speed on-chip oscillator off CM10 = 1 Peripheral clock off VCA27 = VCA26 = VCA25 = 0	-	0.8	3.0	μА
			XIN clock off, Topr = 85°C High-speed on-chip oscillator off Low-speed on-chip oscillator off CM10 = 1 Peripheral clock off VCA27 = VCA26 = VCA25 = 0	-	1.2	_	μА
			XIN clock off, Topr = 125°C High-speed on-chip oscillator off Low-speed on-chip oscillator off CM10 = 1 Peripheral clock off	=	4.0	=	μА

Timing Requirements

(Unless Otherwise Specified: Vcc = 5 V, Vss = 0 V at Topr = 25°C) [Vcc = 5 V]

Table 5.49 XIN Input

Symbol	Parameter		Standard		
			Max.	Unit	
tc(XIN)	XIN input cycle time	50	-	ns	
twh(xin)	XIN input "H" width	25	=	ns	
twl(XIN)	XIN input "L" width	25	-	ns	

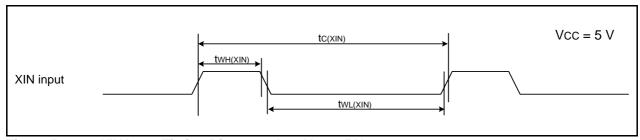


Figure 5.27 XIN Input Timing Diagram when Vcc = 5 V

Table 5.50 TRAIO Input

Symbol	Parameter		Standard		
			Max.	Unit	
tc(TRAIO)	TRAIO input cycle time	100	-	ns	
twh(traio)	TRAIO input "H" width	40	-	ns	
tWL(TRAIO)	TRAIO input "L" width	40	=	ns	

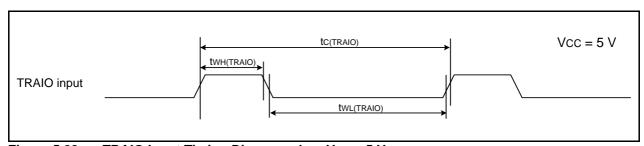


Figure 5.28 TRAIO Input Timing Diagram when Vcc = 5 V

Symbol	Parameter		Standard		
			Max.	Unit	
tc(CK)	CLKi input cycle time	200	=	ns	
tW(CKH)	CLKi input "H" width	100	-	ns	
tW(CKL)	CLKi input "L" width	100	-	ns	
td(C-Q)	TXDi output delay time	-	50	ns	
th(C-Q)	TXDi hold time	0	-	ns	
tsu(D-C)	RXDi input setup time	50	=	ns	
th(C-D)	RXDi input hold time	90	-	ns	

i = 0 or 1

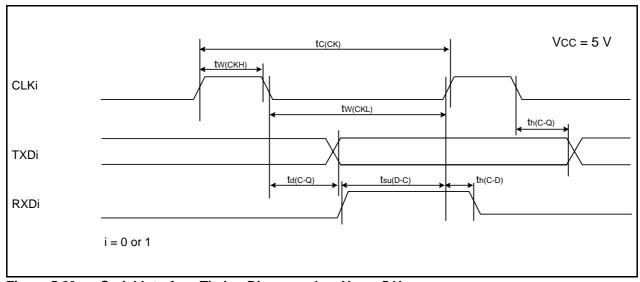


Figure 5.29 Serial Interface Timing Diagram when Vcc = 5 V

Table 5.52 External Interrupt INTi (i = 0, 1, 3) Input

Symbol	Parameter		Standard		
			Max.	Unit	
tW(INH)	INTi input "H" width	250 ⁽¹⁾	-	ns	
tW(INL)	INTi input "L" width	250(2)	-	ns	

- 1. When selecting the digital filter by the INTi input filter select bit, use an INTi input HIGH width of either (1/digital filter clock frequency x 3) or the minimum value of standard, whichever is greater.
- 2. When selecting the digital filter by the INTi input filter select bit, use an INTi input LOW width of either (1/digital filter clock frequency x 3) or the minimum value of standard, whichever is greater.

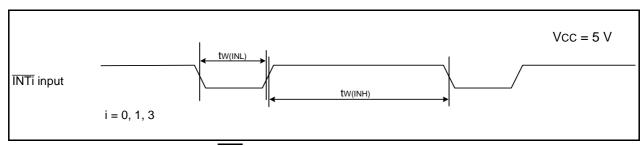


Figure 5.30 External Interrupt INTi Input Timing Diagram when Vcc = 5 V

Table 5.53 Electrical Characteristics (3) [Vcc = 3 V]

Symbol	Parameter		Condition		Si	Unit		
Symbol	Faic	ameter	Condition		Min. Typ. M		Max.	Offic
Vон	Output "H" voltage	Except XOUT	Iон = -1 mA		Vcc - 0.5	-	Vcc	V
		XOUT	Drive capacity HIGH	Iон = -0.1 mA	Vcc - 0.5	_	Vcc	V
			Drive capacity LOW	Іон = -50 μΑ	Vcc - 0.5	=	Vcc	V
Vol	Output "L" voltage	Except XOUT	IoL = 1 mA		_	-	0.5	V
		XOUT	Drive capacity HIGH	IoL = 0.1 mA	=	=	0.5	V
			Drive capacity LOW	IOL = 50 μA	=	=	0.5	V
VT+-VT-	Hysteresis	INTO, INT1, INT3, KIO, KI1, KI2, KI3, TRAIO, RXDO, RXD1, CLKO,CLK1, SSI, SCL, SDA, SSO			0.1	0.3	-	V
		RESET			0.1	0.4	_	V
Іін	Input "H" current	1	VI = 3 V, Vcc = 3	V	_	-	4.0	μΑ
lıL	Input "L" current		VI = 0 V, Vcc = 3'	V	_	-	-4.0	μΑ
RPULLUP	Pull-up resistance		VI = 0 V, Vcc = 3'	V	66	160	500	kΩ
RfXIN	Feedback resistance	XIN			-	3.0	_	MΩ
VRAM	RAM hold voltage	•	During stop mode	Э	2.0	_	-	V

^{1.} Vcc = 2.7 to 3.3 V at Topr = -40 to 85°C (J version) / -40 to 125°C (K version), f(XIN) = 10 MHz, unless otherwise specified.

Table 5.54 Electrical Characteristics (4) [Vcc = 3 V] (Topr = -40 to 85°C (J version) / -40 to 125°C (K version), unless otherwise specified.)

Symbol	Parameter	Parameter Condition	;	Unit			
Symbol	Faiailielei		Condition	Min.	Тур.	Max.	Utill
Icc	Power supply current (Vcc = 2.7 to 3.3 V) Single-chip mode, output pins are open,	High-speed clock mode	XIN = 10 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz No division	-	6	-	mA
ot	other pins are Vss		XIN = 10 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8	-	2	=	mA
		High-speed on-chip oscillator mode	XIN clock off High-speed on-chip oscillator on fOCO = 10 MHz Low-speed on-chip oscillator on = 125 kHz No division	-	5	9	mA
			XIN clock off High-speed on-chip oscillator on fOCO = 10 MHz Low-speed on-chip oscillator on = 125 kHz Divide-by-8	I	2	-	mA
		Low-speed on-chip oscillator mode	XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8, FMR47 = 1	-	130	300	μА
		Wait mode	XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz While a WAIT instruction is executed Peripheral clock operation VCA27 = VCA26 = VCA25 = 0 VCA20 = 1		25	70	μА
			XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz While a WAIT instruction is executed Peripheral clock off VCA27 = VCA26 = VCA25 = 0 VCA20 = 1	-	23	55	μА
		Stop mode	XIN clock off, Topr = 25°C High-speed on-chip oscillator off Low-speed on-chip oscillator off CM10 = 1 Peripheral clock off VCA27 = VCA26 = VCA25 = 0	=	0.7	3.0	μА
			XIN clock off, Topr = 85°C High-speed on-chip oscillator off Low-speed on-chip oscillator off CM10 = 1 Peripheral clock off VCA27 = VCA26 = VCA25 = 0	-	1.1	_	μА
			XIN clock off, Topr = 125°C High-speed on-chip oscillator off Low-speed on-chip oscillator off CM10 = 1 Peripheral clock off VCA27 = VCA26 = VCA25 = 0	-	3.8	_	μА

Timing requirements

(Unless Otherwise Specified: Vcc = 3 V, Vss = 0 V at Topr = 25°C) [Vcc = 3 V]

Table 5.55 XIN Input

Symbol	Parameter		Standard		
			Max.	Unit	
tc(XIN)	XIN input cycle time	100	-	ns	
twh(xin)	XIN input "H" width	40	-	ns	
tWL(XIN)	XIN input "L" width	40	-	ns	

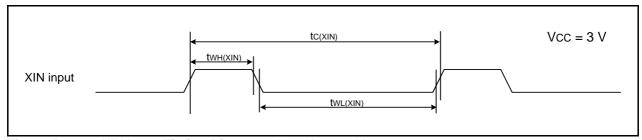


Figure 5.31 XIN Input Timing Diagram when Vcc = 3 V

Table 5.56 TRAIO Input

Symbol	Parameter		Standard		
			Max.	Unit	
tc(TRAIO)	TRAIO input cycle time	300	-	ns	
twh(traio)	TRAIO input "H" width	120	-	ns	
twl(traio)	TRAIO input "L" width	120	=	ns	

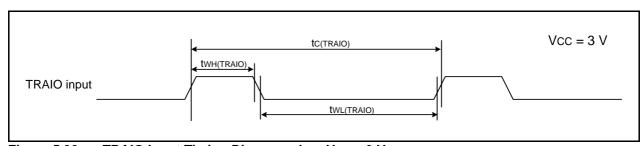


Figure 5.32 TRAIO Input Timing Diagram when Vcc = 3 V

Table 5	57	Serial	Interface

Symbol	Parameter		Standard	
	Faidilletei	Min.	Max.	Unit
tc(CK)	CLKi input cycle time	300	=	ns
tW(CKH)	CLKi input "H" width	150	-	ns
tW(CKL)	CLKi Input "L" width	150	-	ns
td(C-Q)	TXDi output delay time	-	80	ns
th(C-Q)	TXDi hold time	0	-	ns
tsu(D-C)	RXDi input setup time	70	=	ns
th(C-D)	RXDi input hold time	90	-	ns

i = 0 or 1

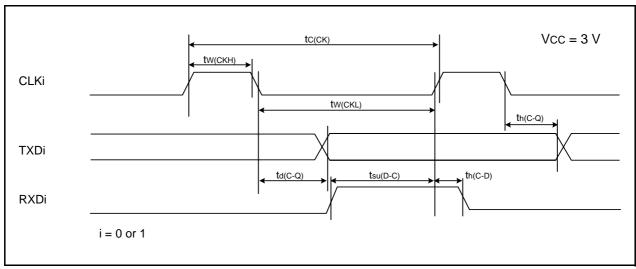


Figure 5.33 Serial Interface Timing Diagram when Vcc = 3 V

Table 5.58 External Interrupt \overline{INTi} (i = 0, 1, 3) Input

Symbol	Parameter		Standard	
			Max.	Unit
tW(INH)	INTi input "H" width	380(1)	_	ns
tW(INL)	INTi input "L" width	380(2)	-	ns

- 1. When selecting the digital filter by the INTi input filter select bit, use an INTi input HIGH width of either (1/digital filter clock frequency × 3) or the minimum value of standard, whichever is greater.
- 2. When selecting the digital filter by the $\overline{\text{INTi}}$ input filter select bit, use an $\overline{\text{INTi}}$ input LOW width of either (1/digital filter clock frequency × 3) or the minimum value of standard, whichever is greater.

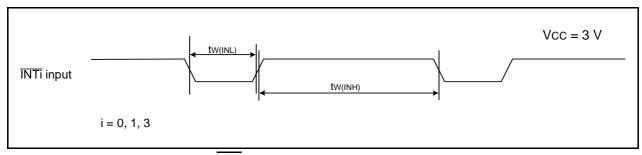
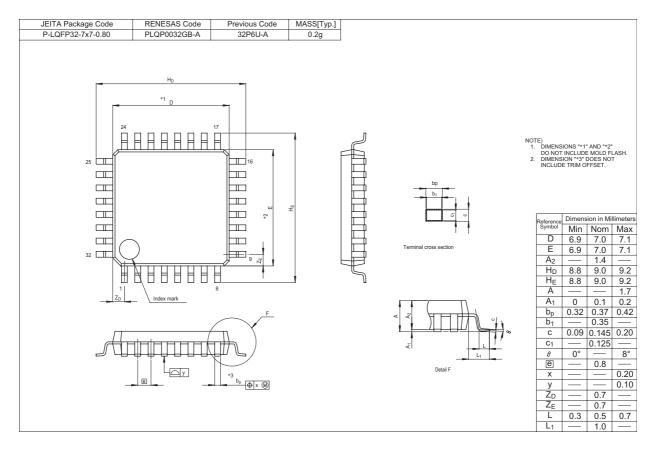


Figure 5.34 External Interrupt INTi Input Timing Diagram when Vcc = 3 V

Package Dimensions

Diagrams showing the latest package dimensions and mounting information are available in the "Packages" section of the Renesas Technology website.



REVISION HISTORY

R8C/26 Group, R8C/27 Group Datasheet

	5.4	Description	
Rev.	Date	Page Summary	
0.10	Nov 14, 2005	-	First edition issued
0.20	Feb 06, 2006	2, 3	Table 1.1 Functions and Specifications for R8C/26Group and Table 1.2 Functions and Specifications for R8C/27 Group; Minimum instruction execution time and Supply voltage revised
		9	Table 1.6 Pin Name Information by Pin Number; "XOUT" \rightarrow "XOUT/XCOUT" and "XIN" \rightarrow "XIN/XCIN" revised
		18	Table 4.4 SFR Information (4); 00FEh: "DRR" → "P1DRR" revised
		19	Table 4.5 SFR Information (5); -0119h: "Timer RE Minute Data Register / Compare Register" → "Timer RE Minute Data Register / Compare Data Register" -011Ah: "Timer RE Time Data Register" → "Timer RE Hour Data Register" -011Bh: "Timer RE Day Data Register" → "Timer RE Day of Week Data Register" revised
		22 to 45	5. Electrical Characteristics added
1.00	Nov 08, 2006	All pages	"Preliminary" deleted
		2	Table 1.1 revised
		3	Table 1.2 revised
		4	Figure 1.1 revised
		5	Table 1.3 revised
		6	Table 1.4 revised
		7	Figure 1.4 revised
		9	Table 1.6 revised
		15	Table 4.1;
			 • 001Ch: "00h" → "00h, 10000000b" revised • 000Fh: "000XXXXXb" → "00X11111b" revised • 0029h: "High-Speed On-Chip Oscillator Control Register 4, FRA4, When shipping" added • 002Bh: "High-Speed On-Chip Oscillator Control Register 6, FRA6, When shipping" added • 0032h: "00h, 01000000b" → "00h, 00100000b" revised • 0038h: "00001000b, 01001001b" → "0000X000b, 0100X001b" revised • NOTE3 and 4 revised; NOTE6 added
		18	Table 4.4; • 00E0h, 00E1h, 00E5h, 00E8h, 00E9h: "XXh" → "00h" revised • 00FDh: "XX00000000b" → "00h" revised
		22	Table 5.2 revised
		23	Figure 5.1 title revised
		24	Table 5.4 revised
		25	Table 5.5 revised
		26	Figure 5.2 title revised and Table 5.7 NOTE4 added

Dov	Data	Description Page Summary	
Rev.	Date		
1.00	Nov 08, 2006	27	Table 5.9, Figure 5.3 revised and Table 5.10 deleted
		28	Table 5.10, Table 5.11 revised
		34	Table 5.15 revised
		35	Table 5.16 revised
		36	Table 5.17 revised
		39	Table 5.22 revised
		40	Table 5.23 revised
		44	Table 5.29 revised
		47	Package Dimensions; "Diagrams showing the latestwebsite." added
1.10	Nov 29, 2006	All pages	"J, K version" added
		1	1 "J and K versions are under developmentnotice." added
			1.1 revised
		2	Table 1.1 revised
		3	Table 1.2 revised
		4	Figure 1.1 NOTE3 added
		5	Table 1.3, Figure 1.2 revised
		6	Table 1.4, Figure 1.3 revised
		7	Figure 1.4 NOTE3 added
		8	Table 1.5 revised
		9	Table 1.6 NOTE2 added
		13	Figure 3.1 revised
		14	Figure 3.2 revised
		15	Table 4.1; "0000h to 003Fh" → "0000h to 002Fh" revised • NOTE3 added
		16	Table 4.2; "0040h to 007Fh" → "0030h to 007Fh" revised • 0032h, 0036h: "After reset" is revised • 0038h: NOTE revised • NOTES 2, 5, 6 revised and NOTE 7, 8 added
		19	Table 4.5 NOTE2 added
		28	Table 5.10 revised
		48 to 66	5.2 J, K Version added
1.20	Jan 17, 2007	18	Table 4.4 NOTE2 added
1.30	May 25, 2007	2	Table 1.1 revised
		3	Table 1.2 revised
		5	Table 1.3 revised
		6	Figure 1.2 revised
		7	Table 1.4 revised
		8	Figure 1.3 revised
		9	Figure 1.4 NOTE4 added
		15	Figure 3.1 part number revised

REVISION HISTORY

R8C/26 Group, R8C/27 Group Datasheet

Rev.	Doto		Description	
Rev.	Date	Page	Summary	
1.30	May 25, 2007	16	Figure 3.2 part number revised	
		30	Table 5.10 revised	
		53	Table 5.39 NOTE4 added	
		55	Table 5.42 revised	
1.40a	Jun 14, 2007	5, 7	Table 1.3 and Table 1.4 revised	
2.00	Mar 01, 2008	1, 49	1.1, 5.2 "J and K versions are" deleted	
		5, 7	Table 1.3, Table 1.4 revised	
		11	Table 1.6 NOTE3 added	
		15, 16	Figure 3.1, Figure 3.2; "Expanded area" deleted	
		17	Table 4.1 "002Ch" added	
		18	Table 4.2 "0036h"; J, K version "0100X000b" → "0100X001b"	
		24, 49	Table 5.2, Table 5.35; NOTE2 revised	
		30	Table 5.10 revised, NOTE4 added	
2.10	Sep 26, 2008	_	"RENESAS TECHNICAL UP DATE" reflected: TN-16C-A172A/E	
		26, 51	Table 5.4, Table 5.37 NOTE2, NOTE4 revised	
		27, 52	Table 5.5, Table 5.38 NOTE2, NOTE5 revised	
		53	Table 5.39 Parameter: Voltage monitor 1 reset generation time added NOTE5 added	
			Table 5.40 revised	
		54	Table 5.41 revised Figure 5.22 revised	

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